

Hamamatsu Photonics K.K.

Symposium University of Tokyo – ETH Zurich – University of Zurich
17 October, 2023

Outline

- About HAMAMATSU
- Product introduction for PMTs
- Product introduction for MPPCs

Yuji Hotta (ETD)

Kensuke Suzuki (ETD)

Kota Kobayashi (SSD)

About HAMAMATSU

Location



HAMAMATSU CITY
Population: 789,822
(As of 1st October, 2023)



Eel (Unagi)



Dumpling (Gyoza)

Location

Switzerland



JAPAN

HAMAMATSU CITY
Population: 789,822
(As of 1st October, 2023)

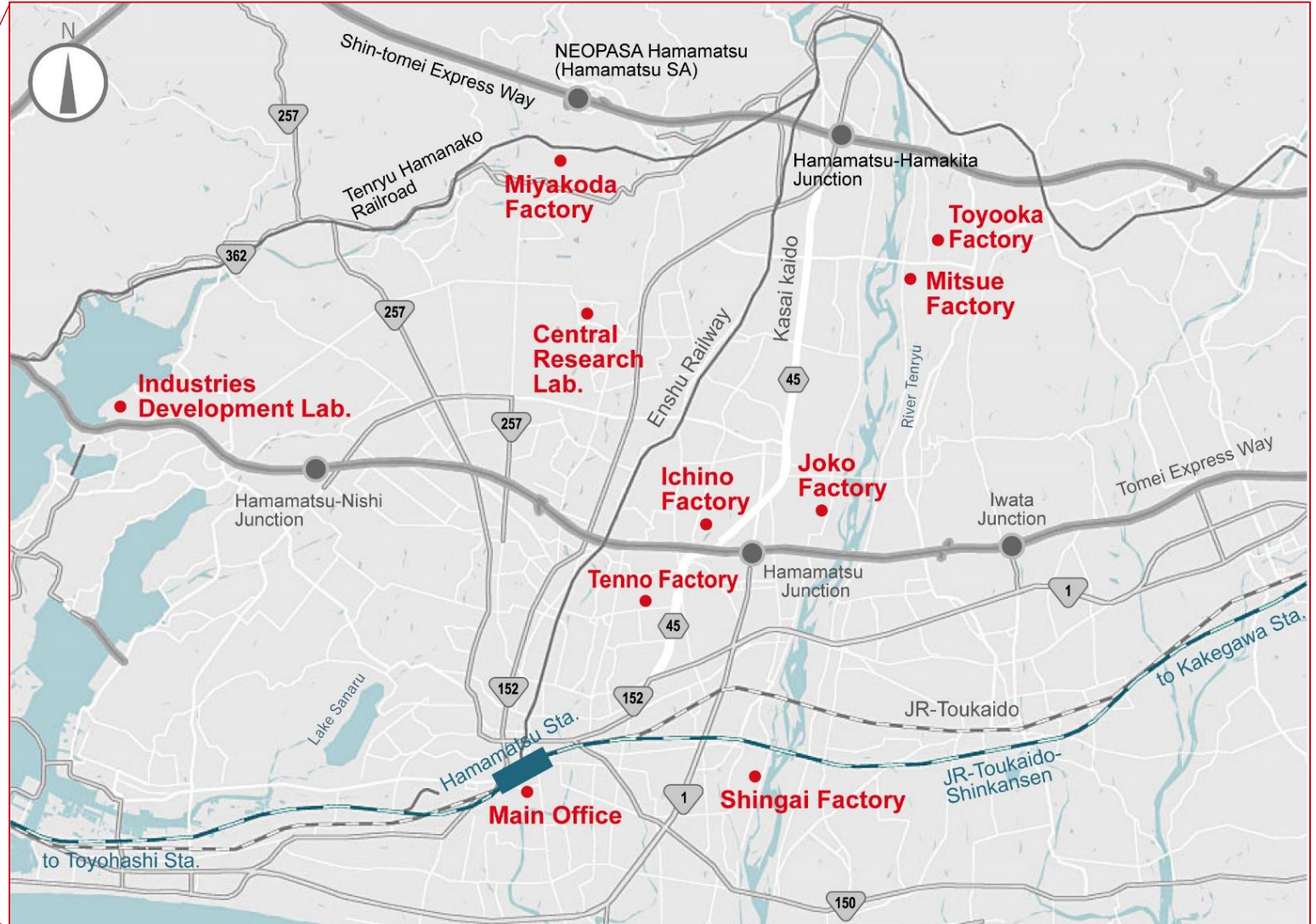


Eel



Dumpling

KAMIOKA
OSAKA
TOKYO
HAMAMATSU



Corporate Data

| | |
|--------------------|---|
| Company Name | HAMAMATSU PHOTONICS K.K. |
| Established | September 29, 1953 |
| Capital | 35,048 million yen |
| Stock listing | Tokyo Stock Exchange, Prime Market |
| Main Product Lines | <ul style="list-style-type: none">▪ Photomultiplier Tubes▪ Imaging Devices▪ Light Sources▪ Opto-semiconductors▪ Imaging and Analyzing Systems |

As of September 30, 2022

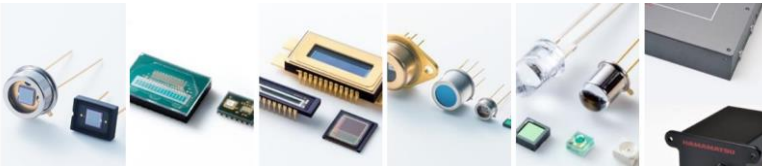
Factories



Electron Tube Division



Solid State Division



Systems Division



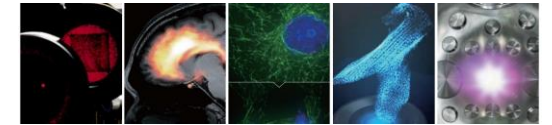
Laser Promotion Division



Laboratories



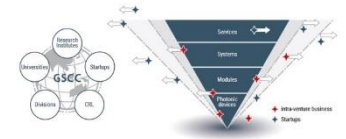
Central Research Laboratory



Other



Global Strategic Challenge Center (GSCC)



Subsidiary



ENERGETIQ TECHNOLOGY, INC.



Number of employees (Japan)

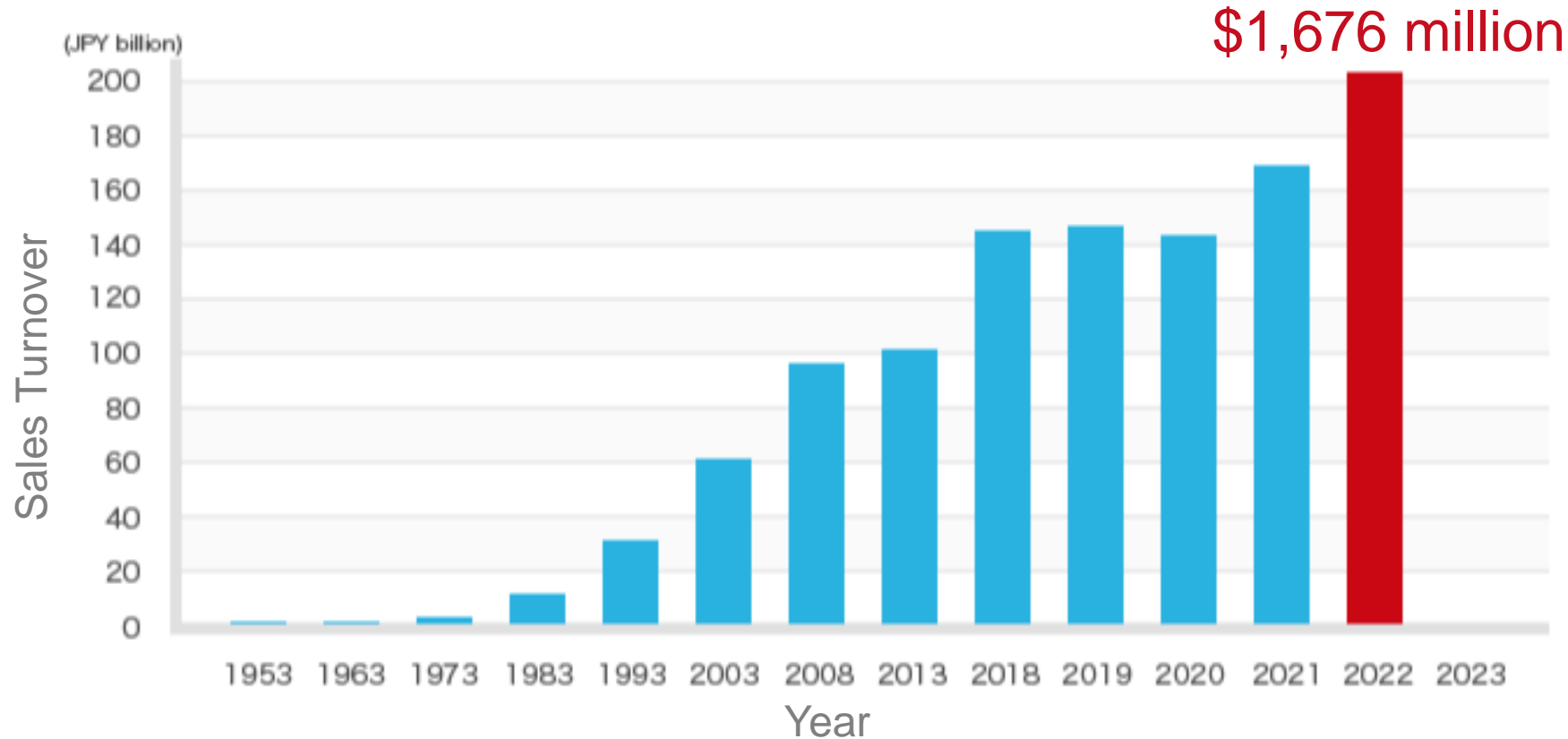
Total

3,973 people

| Business Divisions | Business Sites | Number of people |
|--|--|------------------|
| Electronic Tube Division | Toyooka Factory & Tenno Glass Factory | 1,244 people |
| Solid State Division | Ichino Factory, Mitsue Factory & Shingai Factory | 1,429 people |
| System Division | Joko Factory | 444 people |
| Laser Promotion Division, Compound semiconductor Fab. Center | Miyakoda Factory & Central Research Laboratory | 252 people |
| Global Strategic Challenge Center | Central Research Laboratories & Main Office | 80 people |
| Central Research Laboratory | Central Research Laboratory | 208 people |
| Administration & Managing Office | Main Office (front of Hamamatsu station) | 316 people |

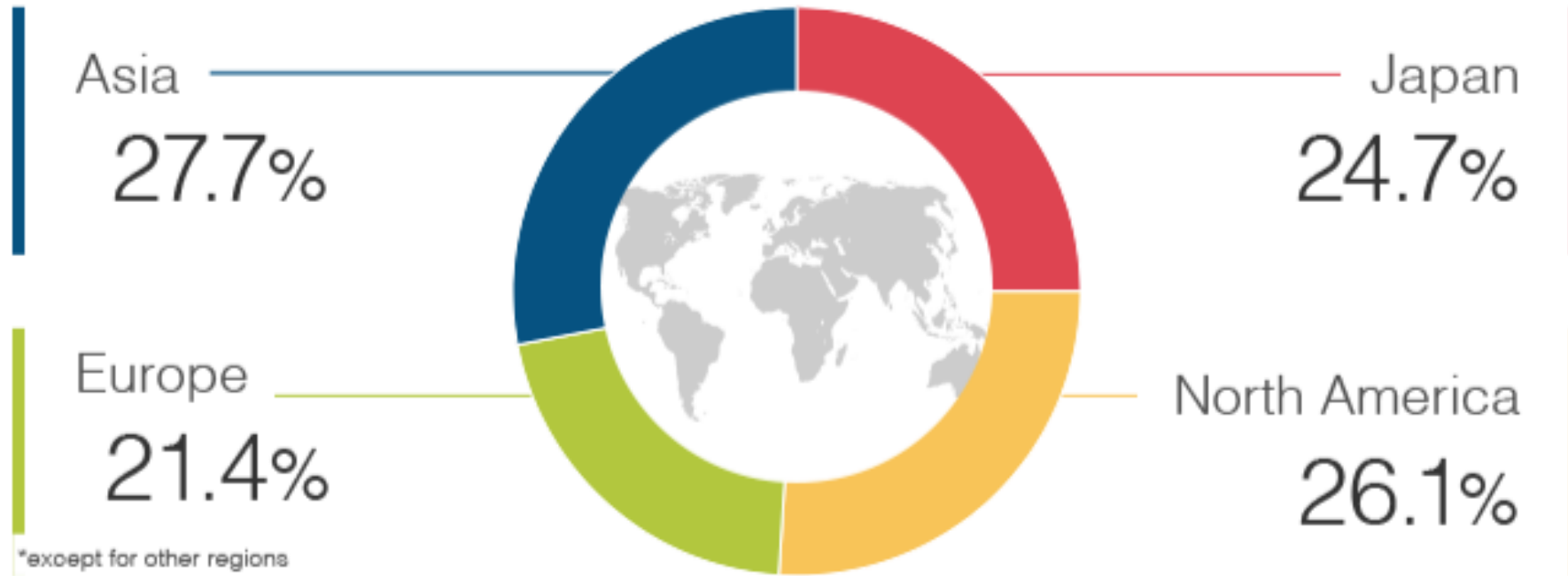
As of January 1, 2023

Sales Turnover



We develop and sell various products using optical technology. In September 2022, consolidated sales reached \$1,676 million. (Converted at an exchange rate of 124.55 yen to the U.S. dollar.)

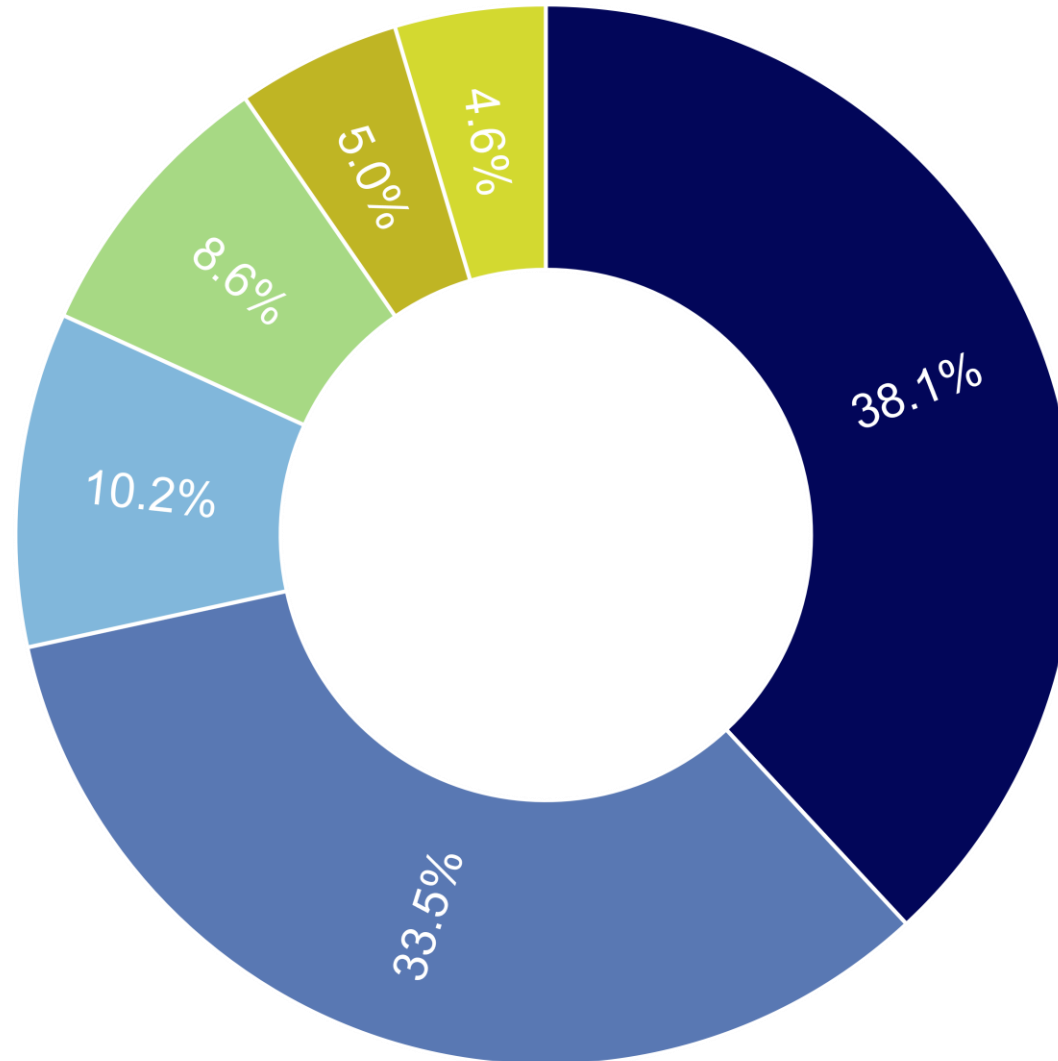
Sales Distribution by Region



* As of September 2022, consolidated

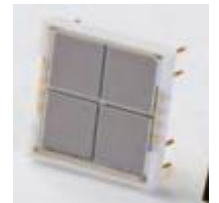
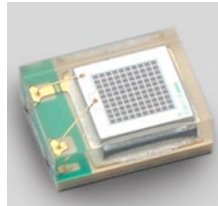
Today, our products are used in over 100 countries.

Percentage of Net Sales



(Fiscal year ended September 2022)

Shipping Record



| Experiment Name | Product | QTY |
|---------------------|---------|---------|
| Super Kamiokande/ID | 20" PMT | 11,200 |
| Super Kamiokande/OD | 8" PMT | 1,900 |
| T2K/ND280/FDG | MPPC | 120,000 |
| MEG | 2" PMT | 850 |
| MEG-II | MPPC | 4,100 |
| XENONnT | 3" PMT | 500 |

<https://www.hamamatsu.com/jp/ja.html>

<https://www.hamamatsu.com/eu/en.html>



PHOTON FAIR 2023

光で何ができるか

2023.11.16(木) 17(金) 18(土) 10:00 - 18:00
(最終日 18日のみ 9:00 - 12:00)

アクトシティ浜松 展示イベントホール

JR 浜松駅北口から徒歩約 10分



完全事前登録制 (入場無料)

事前登録受付中!

www.photonfair.jp

<https://www.photonfair.jp/>

創立70周年を迎えて開催する光の総合展示会



PHOTON FAIR(フォトンフェア)は、浜松ホトニクスが主催する光の総合展示会で、「光で何ができるか」をテーマに5年に一度開催しています。

PHOTON FAIR 2023では浜松ホトニクスの技術や製品を「くらし」「健康」「脳」「地球」「宇宙」「量子」の6つの展示テーマと弊社のコア・テクノロジーに沿って展示します。そのほか、著名なゲストによる特別講演や弊社エンジニア、研究者そして社外講師による30セッション以上のセミナーも開催します。

◀PHOTON FAIR 2018の会場風景

講演会



浜松ホトニクス株式会社
代表取締役社長

丸野 正

光技術による社会貢献と高付加
価値化への挑戦



ブリュッセル自由大学 (VUB)
副学長 兼 教授

ヒューゴ・ティエンボン 氏

光技術が切り拓く新たな世界：
ブリュッセル・フォトニクス研究
チームの視点



東京大学カブリ数物連携宇宙研究機構
特別教授・浜松プロフェッサー

村山 斉 氏

ダークマターとダークエネルギー



宇宙飛行士

野口 聡一 氏

宇宙の魅力や宇宙産業・宇宙
技術開発の現状と今後の発展

浜松ホトニクス株式会社

フォトンフェア事務局

〒430-8587 静岡県浜松市中区砂山町325-6 日本生命浜松駅前ビル E-mail: photonfair@hq.hpkk.co.jp

Product introduction for PMTs

Agenda

- Fast Time Response PMT R13xxx series and R16768-100
- Hemisphere PMT R14374(3" PMT), R14688(8" PMT)
- R12699-406-M4(2" FP-PMT)
- R9880 Series (TO-8 PMT)

Agenda

- Fast Time Response PMT R13xxx series and R16768-100
- Hemisphere PMT R14374(3" PMT), R14688(8" PMT)
- R12699-406-M4(2" FP-PMT)
- R9880 Series (TO-8 PMT)

Fast Time Response PMT R13xxx Series (1)

● Fast Time Response PMT R13xxx Series Spec. Comparison

| Type Name | | R13478 | R13449 | R13408 | R13089 | R15608 |
|---------------------------|--|-----------|---------|---------|---------|---------|
| Size | | 1" | 1-1/8" | 1-1/2" | 2" | 3" |
| Effective Area Min.[mm] | | Φ 22 | Φ 25 | Φ 34 | Φ 46 | Φ 65 |
| Spectral Response | Range [nm] | 300 - 650 | | | | |
| | Peak Wavelength [nm] | 420 | | | | |
| Photocathode Material | | BA | | | | |
| Window Material | | K | | | | |
| Dynode Structure / Stages | | L/8 | L/8 | L/8 | L/8 | L/10 |
| Cathode Characteristics | Luminous Typ. [uA/lm] | 95 | 95 | 95 | 95 | 85 |
| | Blue Sensitivity Index. Typ. | 10 | 10 | 10 | 10 | 9.5 |
| Anode Characteristics | Luminous Typ. [A/lm] | 50 | | | | |
| | Gain Typ. | 5.3E+05 | 5.3E+05 | 5.3E+05 | 3.2E+05 | 9.4E+06 |
| | Dark Current (After 30 min.) Typ. [nA] | 3 | 3 | 3 | 10 | 15 |
| | Dark Current (After 30 min.) Max. [nA] | 30 | 30 | 30 | 50 | 100 |
| | Rise Time Typ. [ns] | 0.9 | 0.9 | 1.2 | 2 | 1.9 |
| | T.T.S. (FWHM) Typ. [ps] | 130 | 170 | 190 | 230 | 400 |
| Pulse Linearity | 2 % Deviation [mA] | 10 | 10 | 20 | 30 | 30 |



- Main Feature
- Fast Time Response
- High Time Resolution

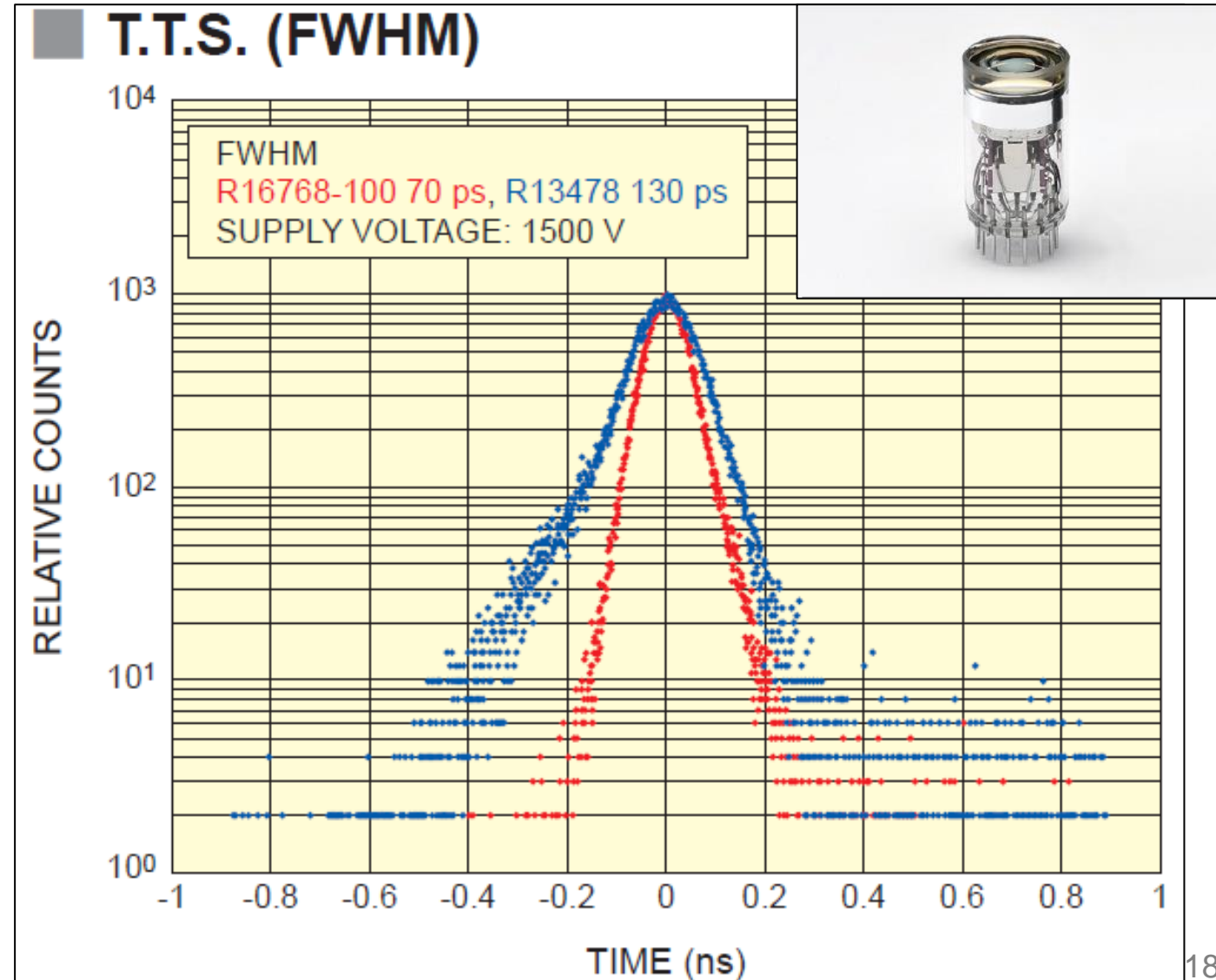
Mainly Used for TOF experiment, radiation monitoring.

Fast Time Response PMT R13xxx Series (2)

- R13478 & R16768-100 Spec. Comp.

| Type Name | | R13478 | R16768-100 |
|---------------------------|--|-----------|------------|
| Size | | 1" | 1" |
| Effective Area Min. [mm] | | Φ 22 | Φ 12 |
| Spectral Response | Range [nm] | 300 - 650 | 160 - 650 |
| | Peak Wavelength [nm] | 420 | 350 |
| Photocathode Material | | BA | SBA |
| Window Material | | K | Q |
| Dynode Structure / Stages | | L/8 | L/8 |
| Cathode Characteristics | Luminous Typ. [uA/lm] | 95 | 120 |
| | Blue Sensitivity Index. Typ. | 10 | 12.5 |
| Anode Characteristics | Luminous Typ. [A/lm] | 50 | 180 |
| | Gain Typ. | 5.3E+05 | 1.5E+06 |
| | Dark Current (After 30 min.) Typ. [nA] | 3 | 3 |
| | Dark Current (After 30 min.) Max. [nA] | 30 | 30 |
| | Rise Time Typ. [ns] | 0.9 | 0.9 |
| | T.T.S. (FWHM) Typ. [ps] | 130 | 70 |
| Pulse Linearity | 2 % Deviation [mA] | 10 | 10 |

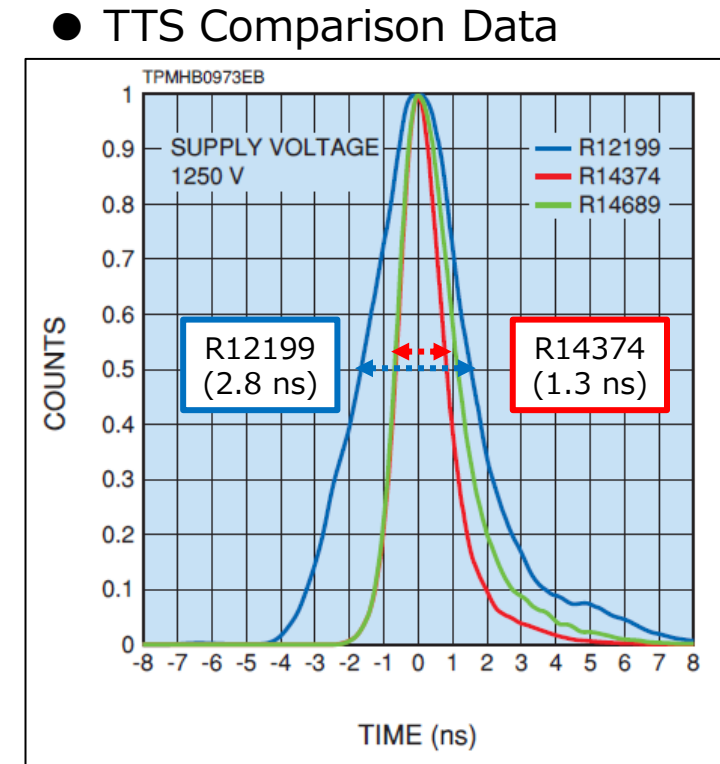
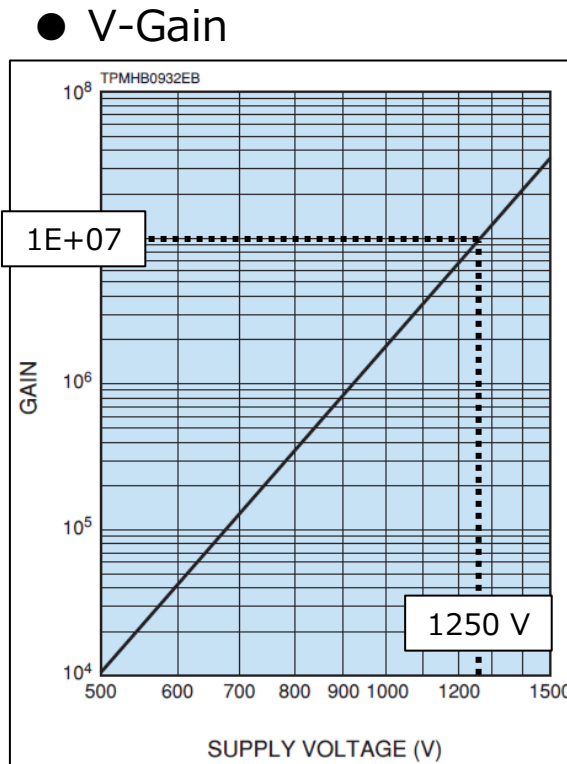
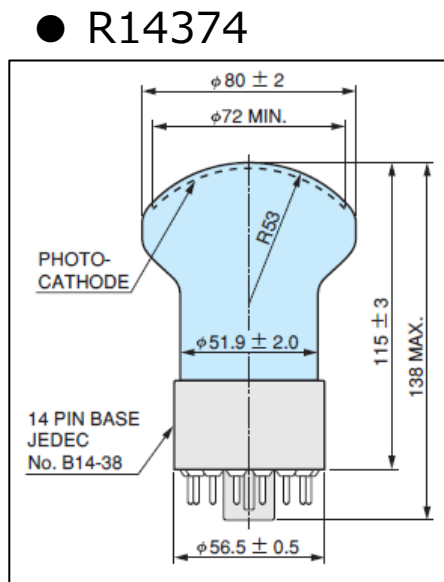
- R13478 & R16768-100 TTS Data Comparison



Agenda

- Fast Time Response PMT R13xxx series and R16768-100
- Hemisphere PMT R14374(3" PMT), R14688(8" PMT)
- R12699-406-M4(2" FP-PMT)
- R9880 Series (TO-8 PMT)

Hemisphere 3" PMT R14374 Series



● R12199/R14374 Spec. Comparison

| Type Name | | R12199 | R14374 |
|---------------------------|---------------------------------------|------------|------------|
| Size | | 3" | |
| Effective Area Min. [mm] | | Φ 72 | |
| Spectral response | Range [nm] | 300 to 650 | |
| | Peak Wavelength [nm] | 420 | |
| Photocathode material | | BA | |
| Window material | | K | |
| Dynode structure / Stages | | C&LF / 10 | |
| Cathode characteristics | Luminous Typ. [uA/lm] | 90 | |
| | Blue sensitivity index Typ. | 11 | |
| Anode characteristics | Luminous Typ. [A/lm] | 900 | |
| | Gain Typ. | 1.0E+07 | |
| | Dark current (After 30 min) Typ. [nA] | 50 | |
| | Rise Time Typ. [ns] | 3 | 2.9 |
| Transit Time Typ. [ns] | | 35 | 35 |
| T.T.S. (FWHM) Typ. [ns] | | 2.8 | 1.3 |

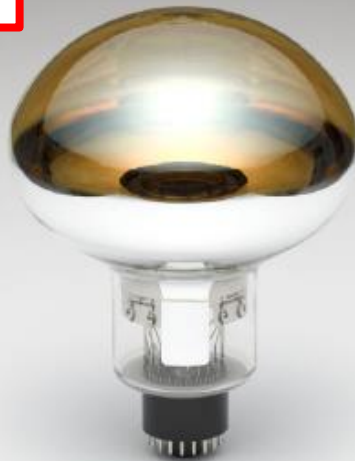
- Main Feature
 - High Gain
 - High Time Resolution
- Mainly Used for HEP experiment

Hemisphere 8" PMT R14688 Series (1)

R5912



R14688



● R5912 & R14688 Specification Comparison

| Parameter | R5912 | R14688 | Unit |
|---|-----------------------|--------|------|
| Diameter | 202 dia. | | mm |
| Effective area (Min.) | 190 dia. | | mm |
| Spectral response | 300 to 650 | | nm |
| Photocathode | BA/SBA | | - |
| Gain | 1.0 x 10 ⁷ | | - |
| Applied voltage for gain of 1.0 x 10 ⁷ | 1500 | 1750 | V |
| Rise time | 3.6 | 2.2 | ns |
| Electron transit time | 54 | 37 | ns |
| T.T.S. (FWHM) | 2.4 | 1.0 | ns |

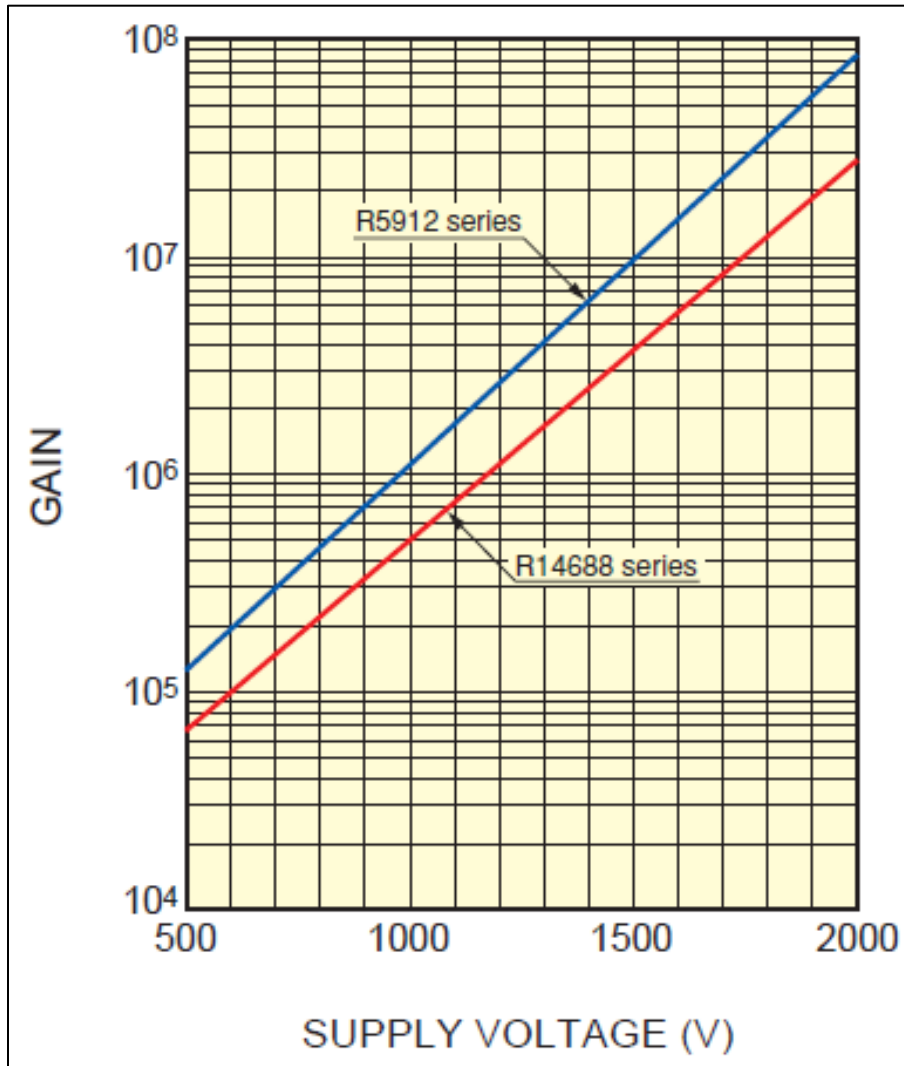
Main Feature

- High Gain
- **Large Size with High Time Resolution**

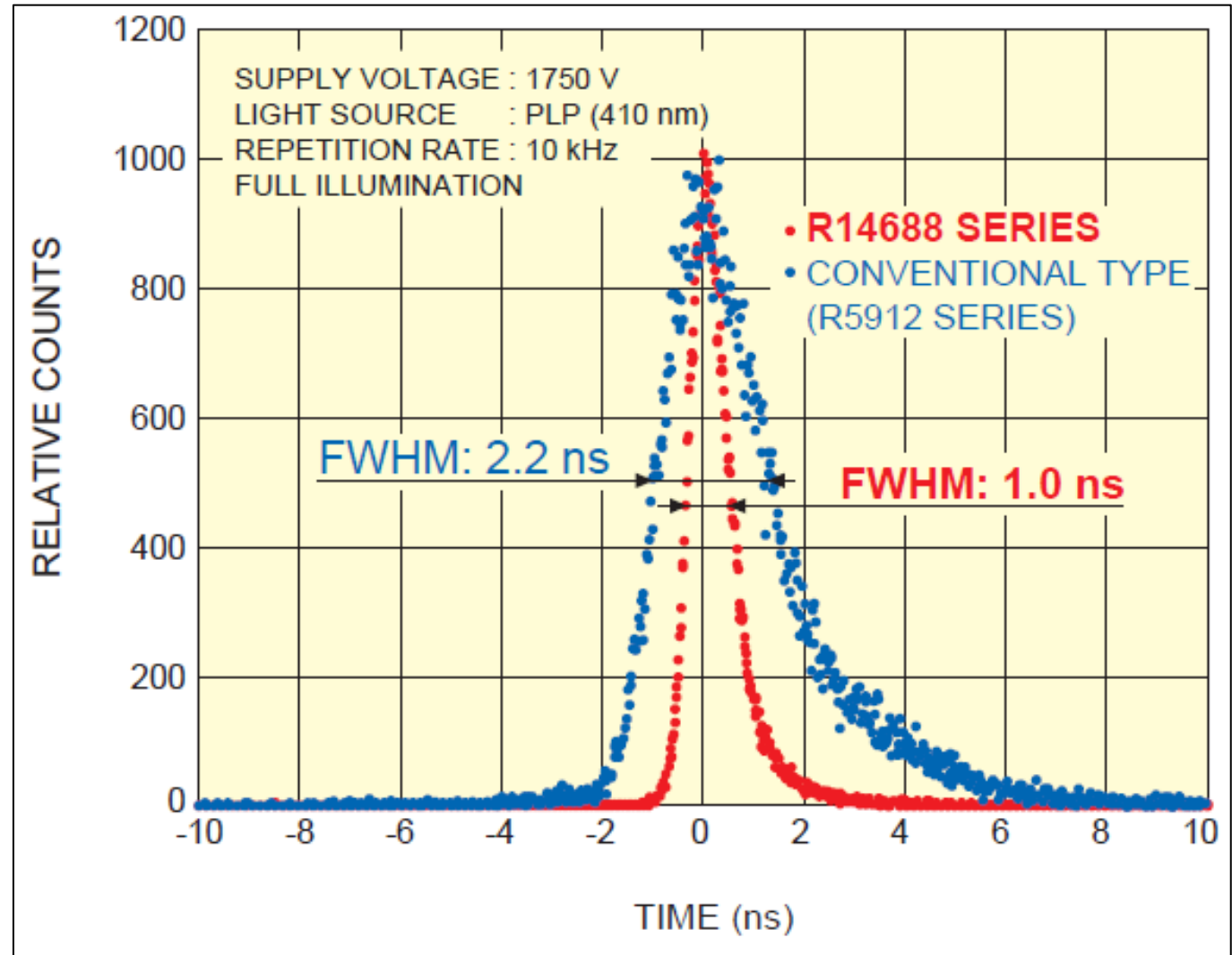
Mainly Used for HEP Experiment

Hemisphere 8" PMT R14688 Series (2)

● R5912 & R14688 Gain Comparison Data



● R5912 & R14688 TTS Comparison Data



Agenda

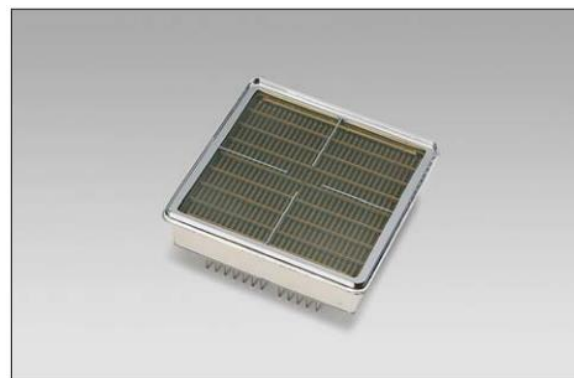
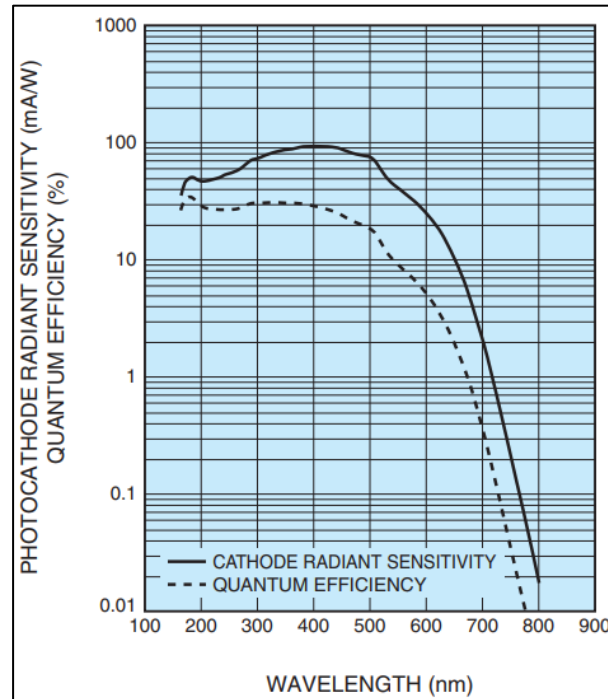
- Fast Time Response PMT R13xxx series and R16768-100
- Hemisphere PMT R14374(3" PMT), R14688(8" PMT)
- R12699-406-M4(2" FP-PMT)
- R9880 Series (TO-8 PMT)

2" Square Flat-Panel-PMT R12699-406-M4(1)

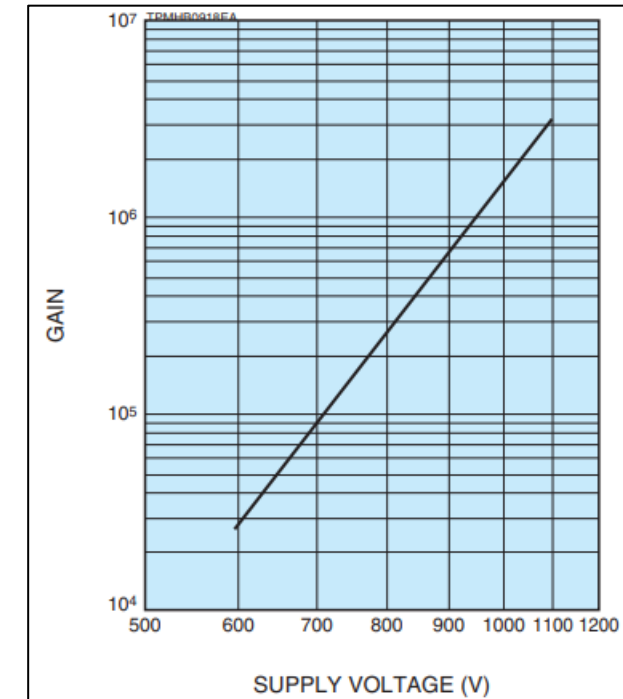
● Specification

| | | |
|------------------------------------|------------------------------------|---------------|
| Type Name | | R12699-406-M4 |
| Size | | 2" □ |
| Effective Area Min. [mm] | | 48.5 × 48.5 |
| Spectral response | Range [nm] | 160 to 650 |
| | Peak Wavelength [nm] | 400 |
| Photocathode material | | BA |
| Window material | | Q |
| Cathode characteristics | Luminous Typ. [uA/lm] | 95 |
| | Blue sensitivity index Typ. | 10 |
| Anode characteristics | Luminous Typ. [A/lm] | 140 |
| | Gain Typ. | 1.5E+06 |
| | Dark current per channel Typ. [nA] | 1.5 |
| | Dark current in total Typ. [nA] | 6 |
| | Rise Time Typ. [ns] | 1.2 |
| | T.T.S. (FWHM) Typ. [ns] | 0.41 |
| Pulse Linearity | 2 % deviation [mA] | 8 |
| Storage temperature [°C] | | -110 to +50 |
| Operating ambient temperature [°C] | | -110 to +50 |

● QE Curve



● Gain Curve



Main Feature:

Operable at Cryogenic temperature down to -110°C

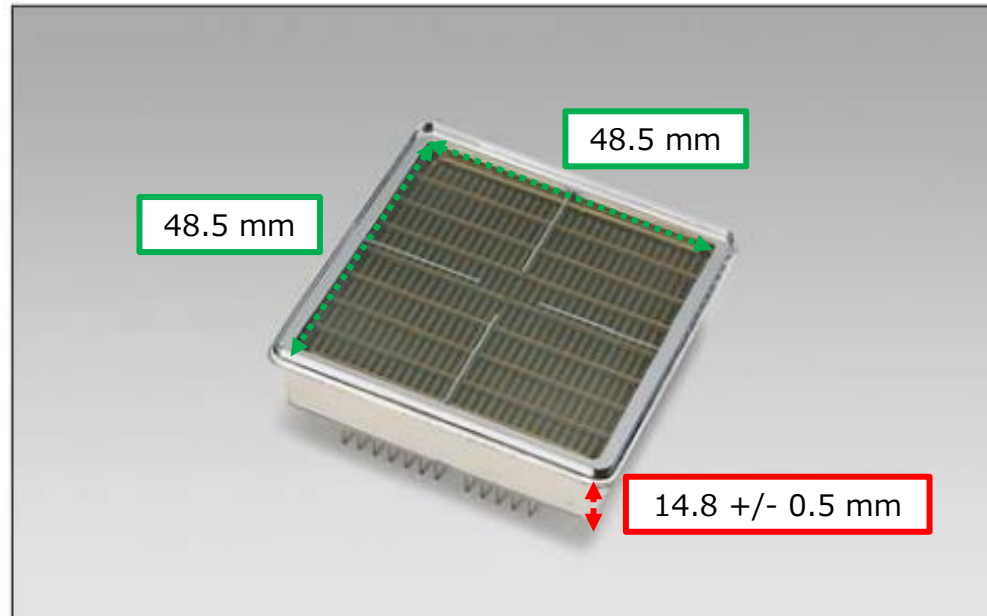
Low Radioactivity, Small height

Wide Effective area

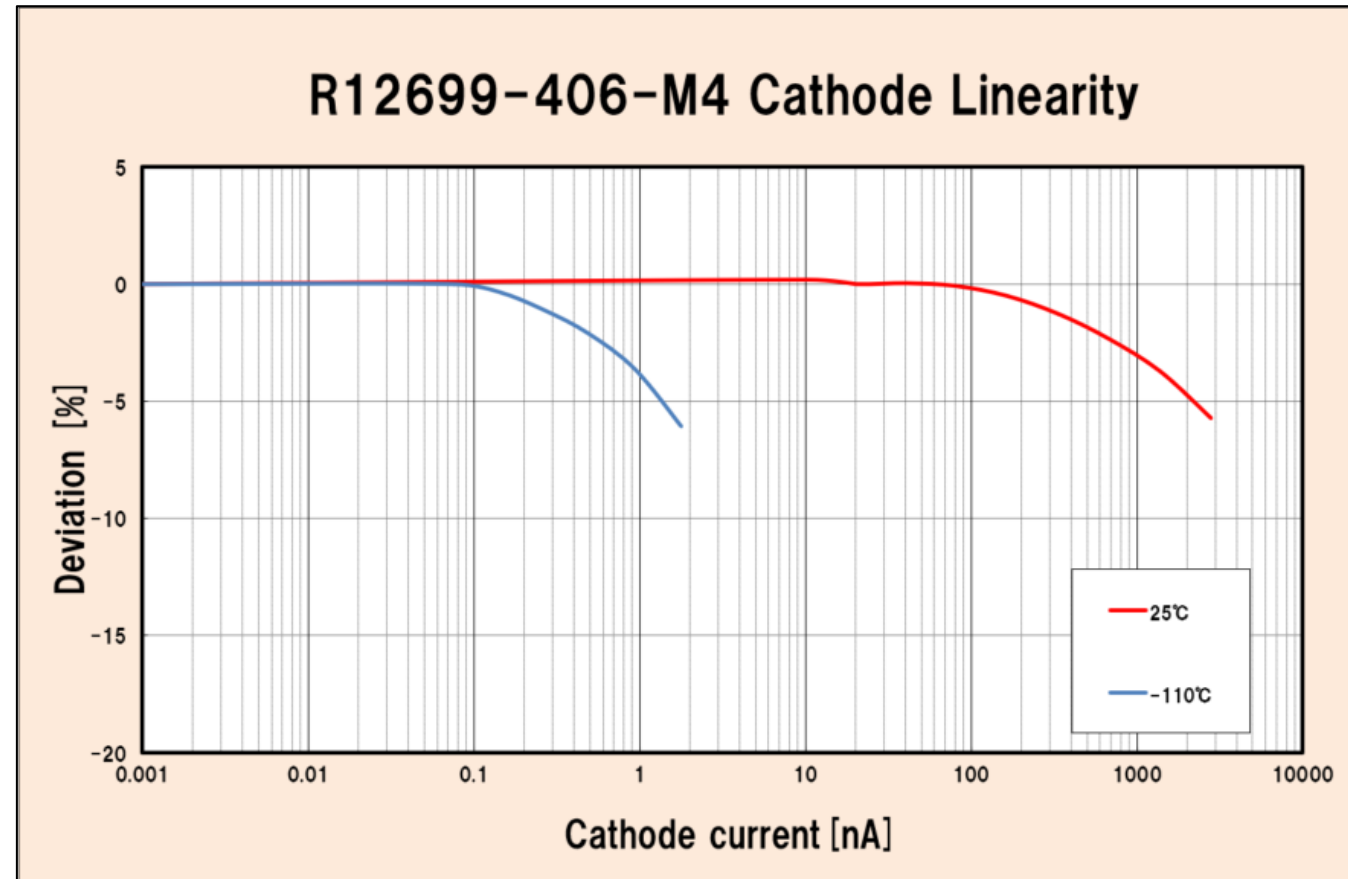
Mainly Used for dark matter experiment

2" Square Flat-Panel-PMT R12699-406-M4(2)

● R12699-406-M4 Cathode Linearity at low temperature



| | K-40 [mBq/sample] | U [mBq/sample] | Th [mBq/sample] | 60Co [mBq/sample] | total [mBq/sample] |
|--------------------------|----------------------|-------------------|--------------------|----------------------|-----------------------|
| R12699-406-M4 | 20.0 | 0.0 | 0.0 | 0.0 | 20.0 |
| Minimum detectable value | - | 5~23 | 2~6 | 2~3 | - |



•The value “0.0” shows that we could not measure the radioactive component correctly because of detection limit.

Agenda

- Fast Time Response PMT R13xxx series and R16768-100
- Hemisphere PMT R14374(3" PMT), R14688(8" PMT)
- R12699-406-M4(2" FP-PMT)
- R9880 Series (TO-8 PMT)

TO-8 PMT R9880 Series (1)

● Specification

| Parameter | | Value | | | | | | | | Unit | |
|----------------------------------|--|---------------|----------------------------|------|------|------|------|-----|-------|------|------|
| Suffix | | -09 | -116 | -113 | -110 | -210 | -04 | -01 | -20 | — | |
| Dynode | Structure | Metal channel | | | | | | | | — | |
| | Stages | 10 | | | | | | | | — | |
| Maximum ratings | Supply voltage between anode and cathode | 1100 | | | | | | | | V | |
| | Average anode output current in total ^② | 0.01 | 0.1 | | | | | | | | mA |
| Cathode | Luminous | Min. | 80 | | 100 | | 350 | | μA/lm | | |
| | | Typ. | 105 | | 135 | | 500 | | | | |
| | Blue sensitivity index | Typ. | 13.5 | | 15.5 | | — | | — | | |
| | Red / White ratio | Typ. | — | | 0.2 | | 0.45 | | — | | |
| Radiant sensitivity ^③ | Typ. | 35 | 110 | | 130 | | 77 | | 78 | mA/W | |
| | Min. | 80 | | 100 | | 350 | | | | | |
| Anode ^④ | Luminous | Typ. | 210 | | 270 | | 400 | | 1000 | | A/lm |
| | | Gain | Typ. 2.0 x 10 ⁶ | | | | | | | | — |
| | Dark current ^⑤ | Typ. | 0.1 | | 1 | | 10 | | | | nA |
| | | Max. | 1 | | 10 | | 100 | | | | |
| | Time response | Rise time | Typ. 0.57 | | | | | | | | ns |
| | | Transit time | Typ. 2.7 | | | | | | | | |
| T.T.S. | | Typ. 0.2 | | | | | | | | | |
| Operating ambient temperature | | -30 to +50 | | | | | | | | °C | |
| Storage temperature | | -30 to +50 | | | | | | | | °C | |



Main Feature

- Small and compact
- Fast time response, high gain

Mainly used for fluorescence observation, radiation monitoring etc..

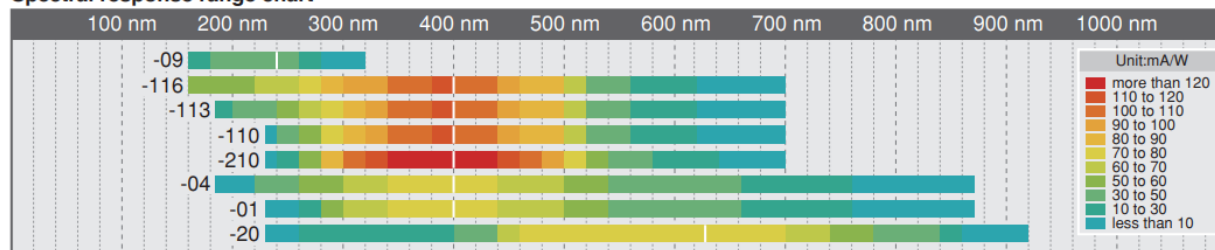
● Spectral response range chart

| Type No. | -09 | -116 | -113 | -110 | -210 | -04 | -01 | -20 | Unit | |
|---------------------------|--------|------------|------------|------------|------------|-----|------------|------------|------------|----|
| Photocathode ^① | Cs-Te | SBA | | | UBA | MA | | ERMA | — | |
| Spectral response | Range | 160 to 320 | 160 to 700 | 185 to 700 | 230 to 700 | | 185 to 870 | 230 to 870 | 230 to 920 | nm |
| | Peak | 240 | | 400 | | | | 630 | | nm |
| Window material | Quartz | | UV | K | | UV | K | | — | |

NOTE: ^① Photocathode materials

SBA: Super bialkali, UBA: Ultra bialkali, MA: Multialkali, ERMA: Extended red multialkali

Spectral response range chart

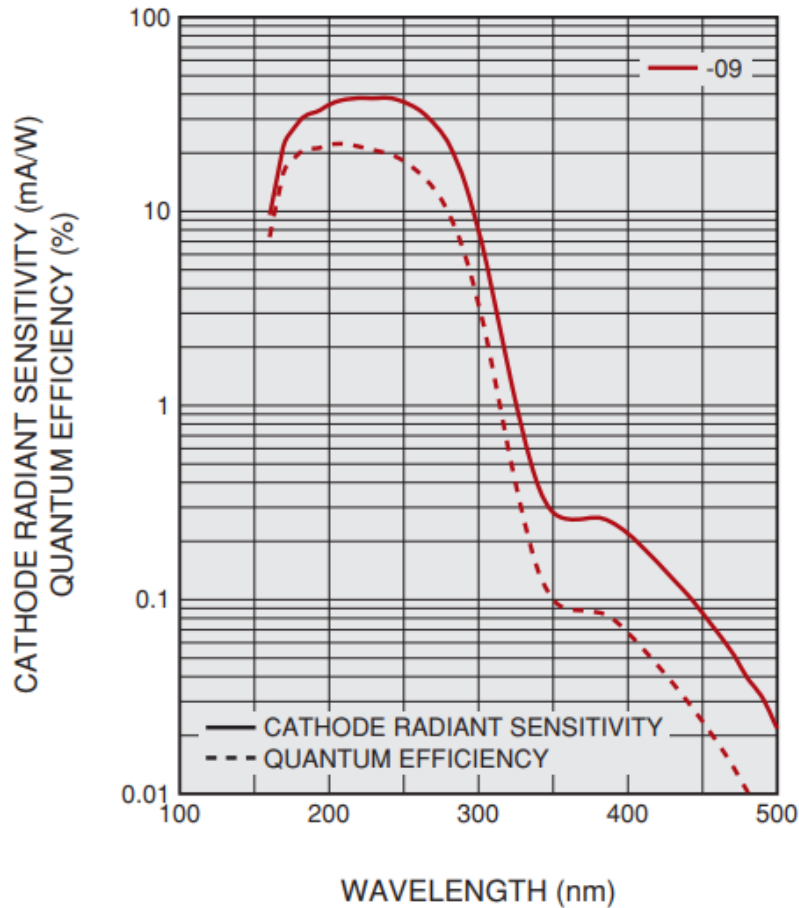


Extended green photocathode type of R9880 is under development and will be released in 2024.

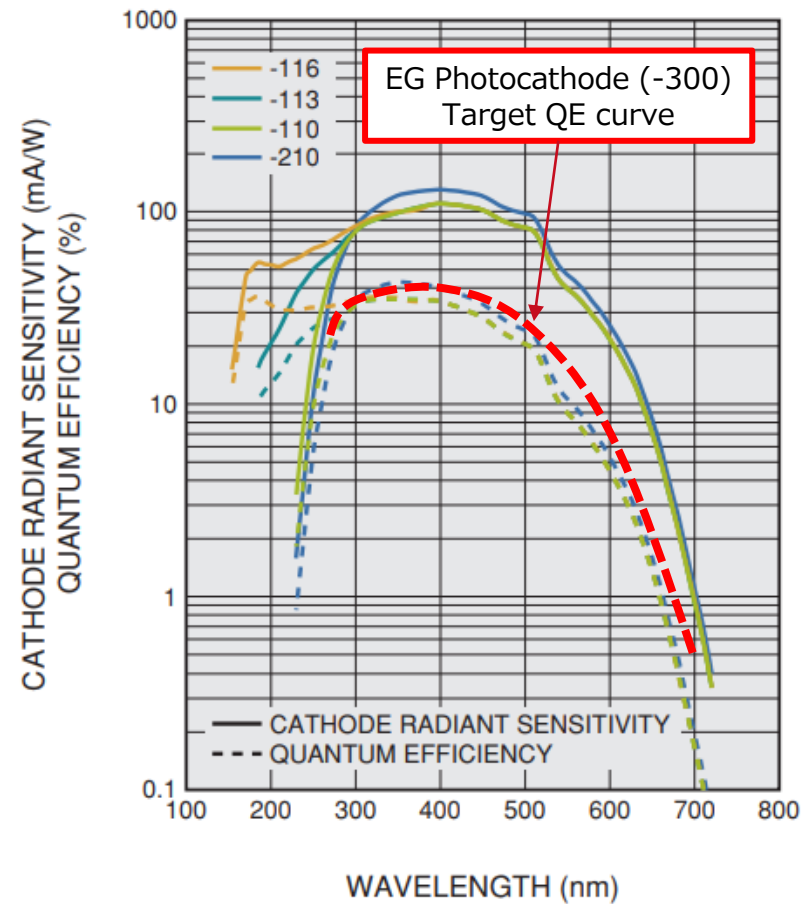
We have a variety in accessories for R9880, like E10679 series, E13643(D-type), C16138(DA-type) and PMT modules.

TO-8 PMT R9880 Series (2)

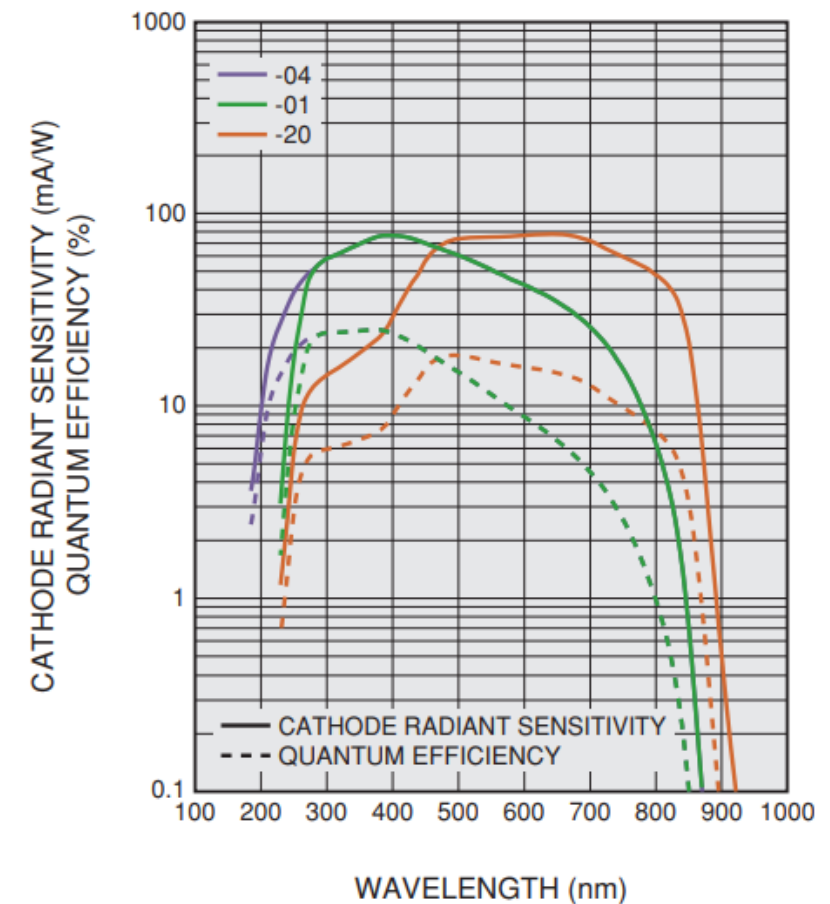
● CsTe Spectral response



● SBA/UBA Spectral response

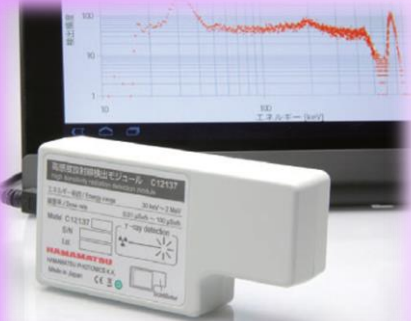


● MA/ERMA Spectral response



Product introduction for MPPCs

**Radiation
detection**

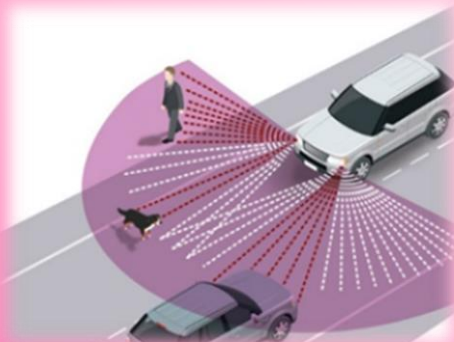


Medical



MPPC (SiPM)

LiDAR



Academic



https://www.nidec-copal-electronics.com/j/featuring/lidar-polygon/vs_gatvo/

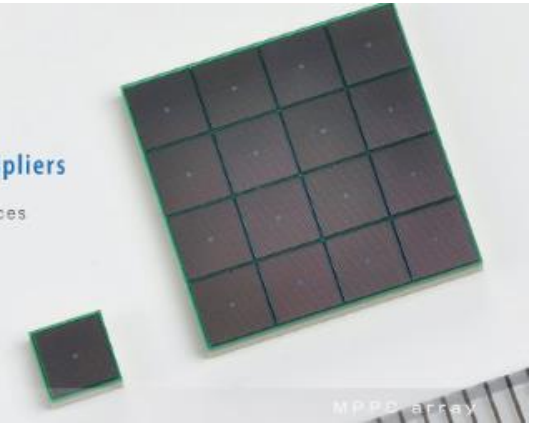
<http://ndip.in2p3.fr/ndip08/Presentations/4Wednesday/A-Midi/39-Yokoyama.pdf>



MPPC[®]
Multi-Pixel Photon Counter

Silicon Photomultipliers

Photon-counting devices
with low afterpulsing,
low crosstalk, and
wide dynamic range

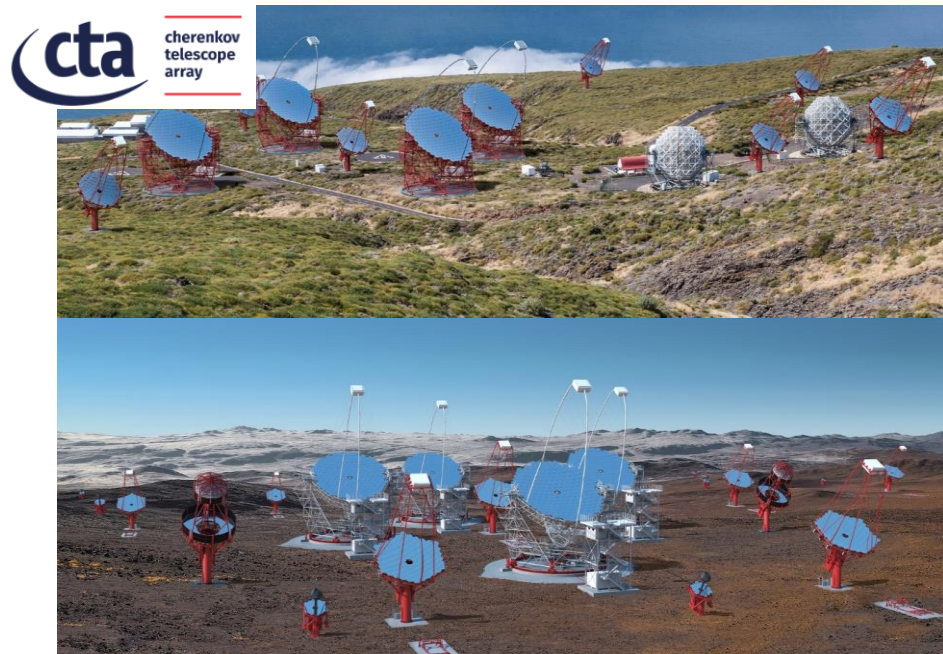


➔ **Focus on in this presentation**

- **NUV Sensitivity MPPC**
- **VUV Sensitivity MPPC**

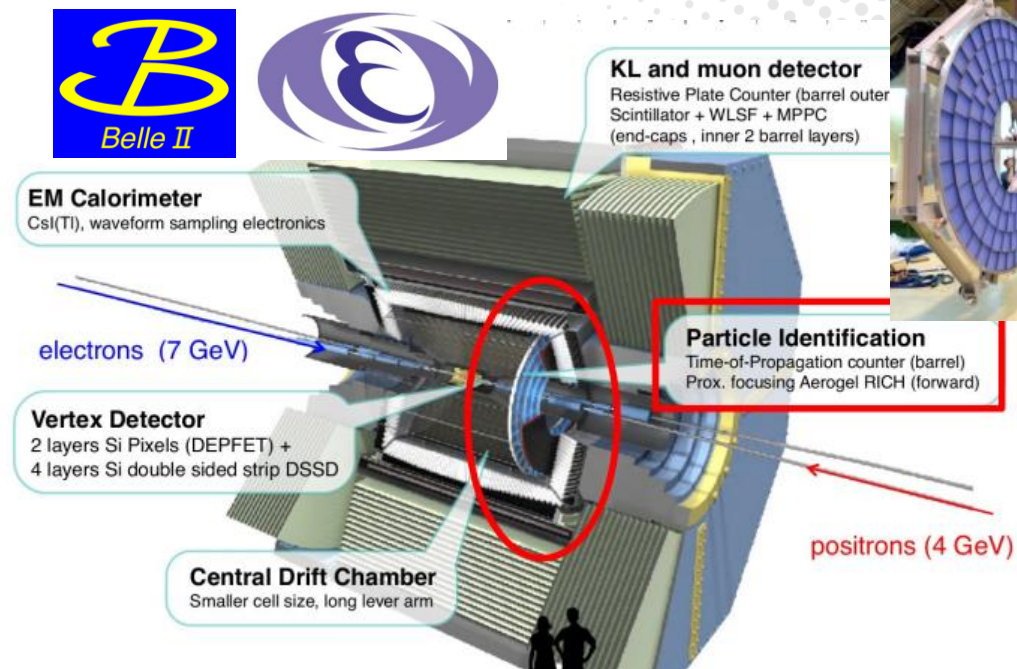
NUV sensitivity MPPC For Cherenkov light detection

Atmospheric Cherenkov light detection



<https://www.cta-observatory.org/about/how-cta-works/>

Silica aerogel Cherenkov radiators

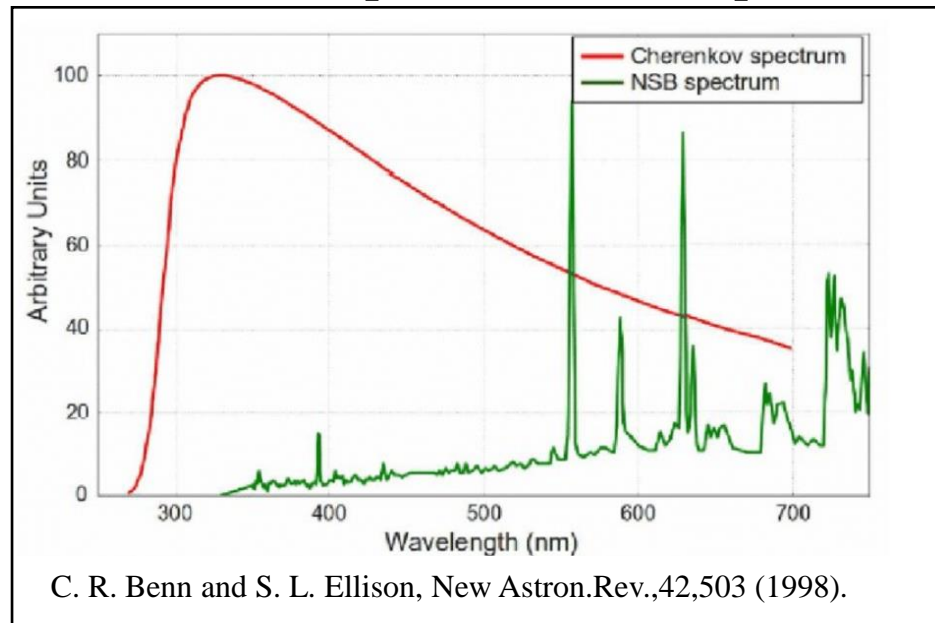


https://indico.inp.nsk.su/event/20/contributions/958/attachments/554/639/INSTR20_Belle2ARICH.pdf

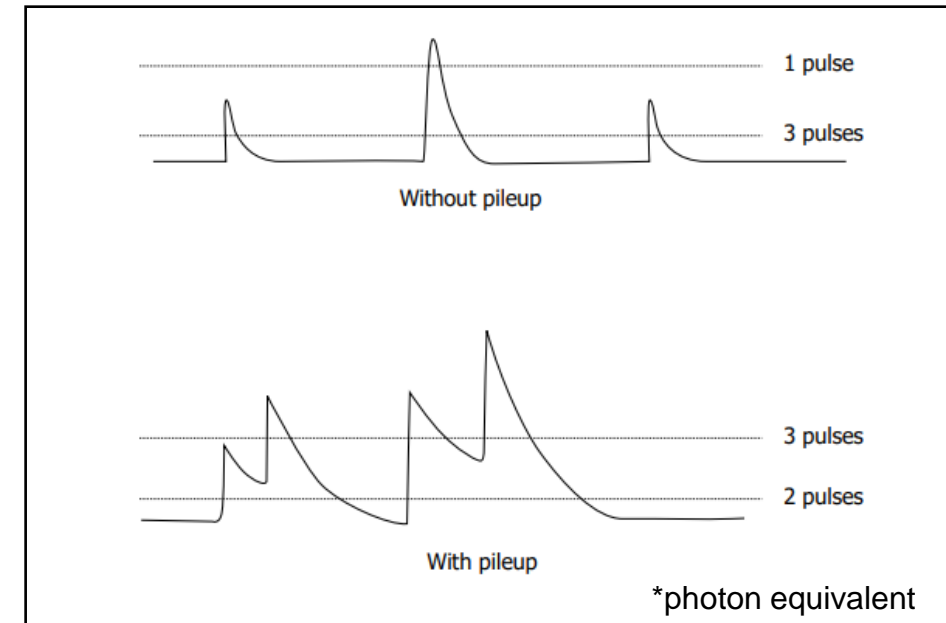
NUV sensitivity MPPC: development themes

- 1 High NUV sensitivity
- 2 Pile-up suppression
- 3 Large active area and small dead space with NUV transmissive window

Cherenkov spectrum in atmosphere



Pile-up phenomenon





High NUV sensitivity for Cherenkov light detection

Purpose

improvement of NUV sensitivity

Approach

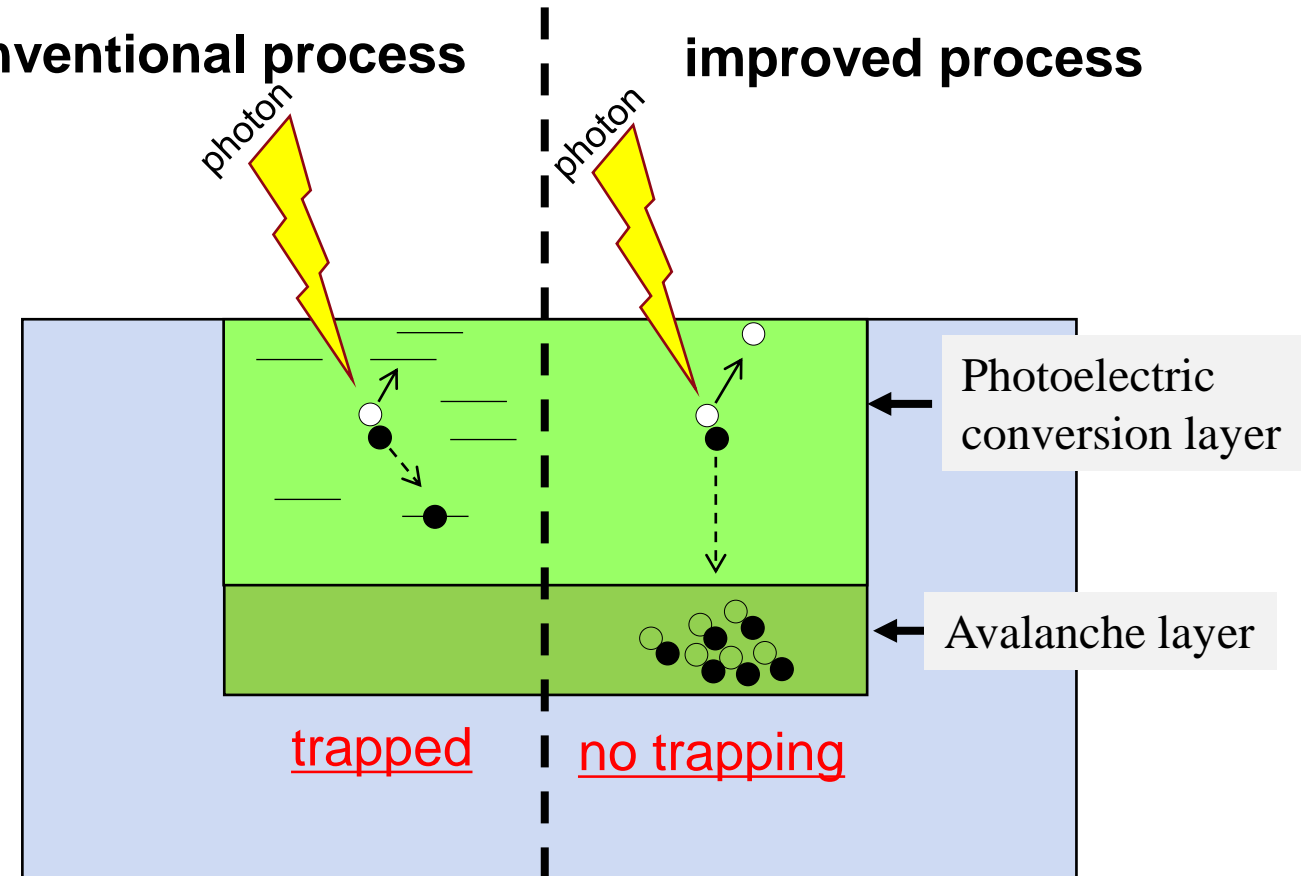
improving wafer processing for lattice defects reduction in the photoelectric conversion layer

Effect

increase number of carriers which reaches to the avalanche layer

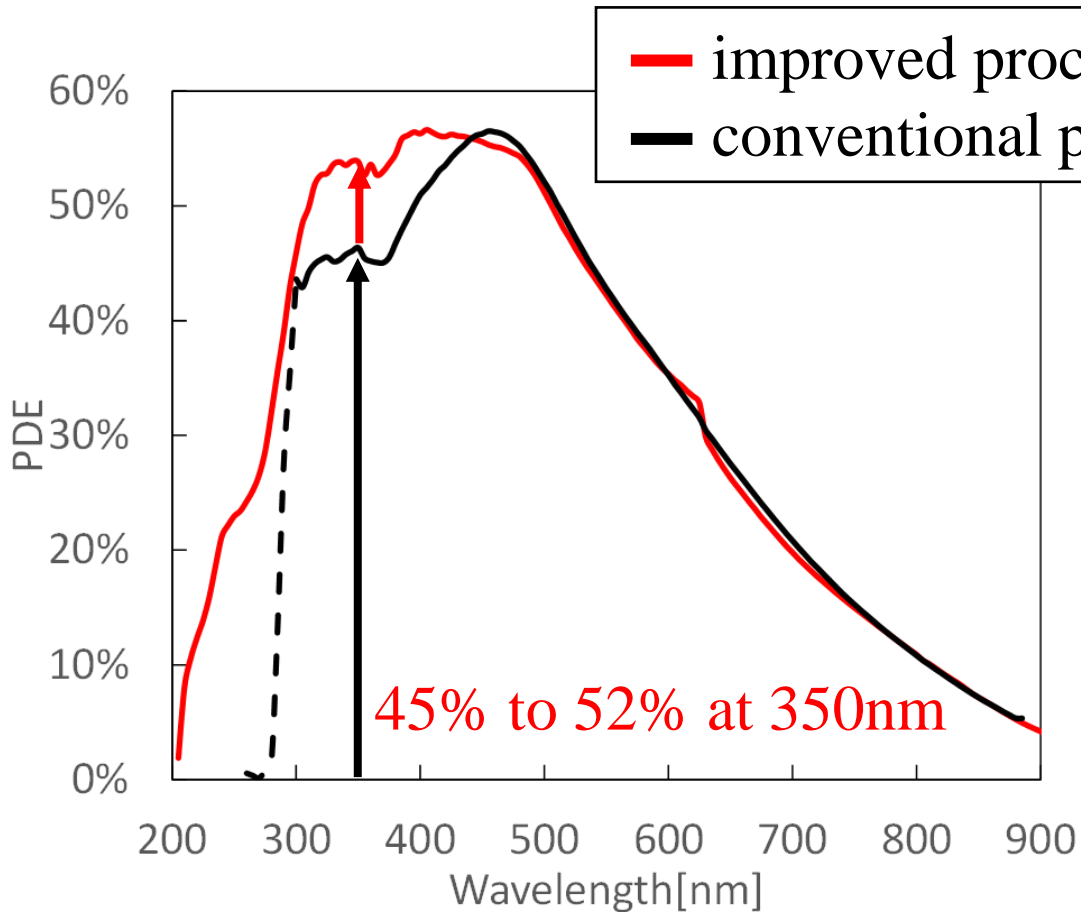
conventional process

improved process





High NUV sensitivity for Cherenkov light detection



Sensitivity at 350 nm improved by 1.16 times

- As a good side effect, the improved process also reduced terminal capacitance ($56\text{pF}/\text{mm}^2 \rightarrow 36\text{pF}/\text{mm}^2$)

Purpose

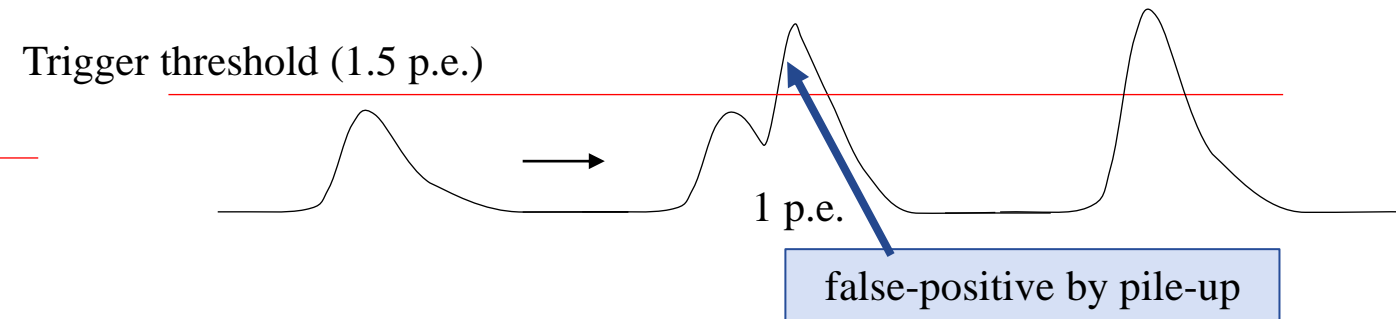
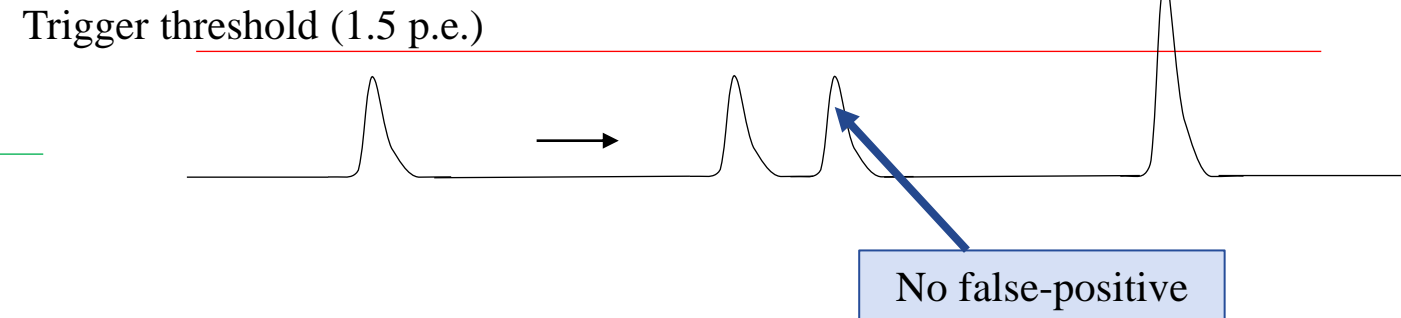
suppression of output pile-up

Approach

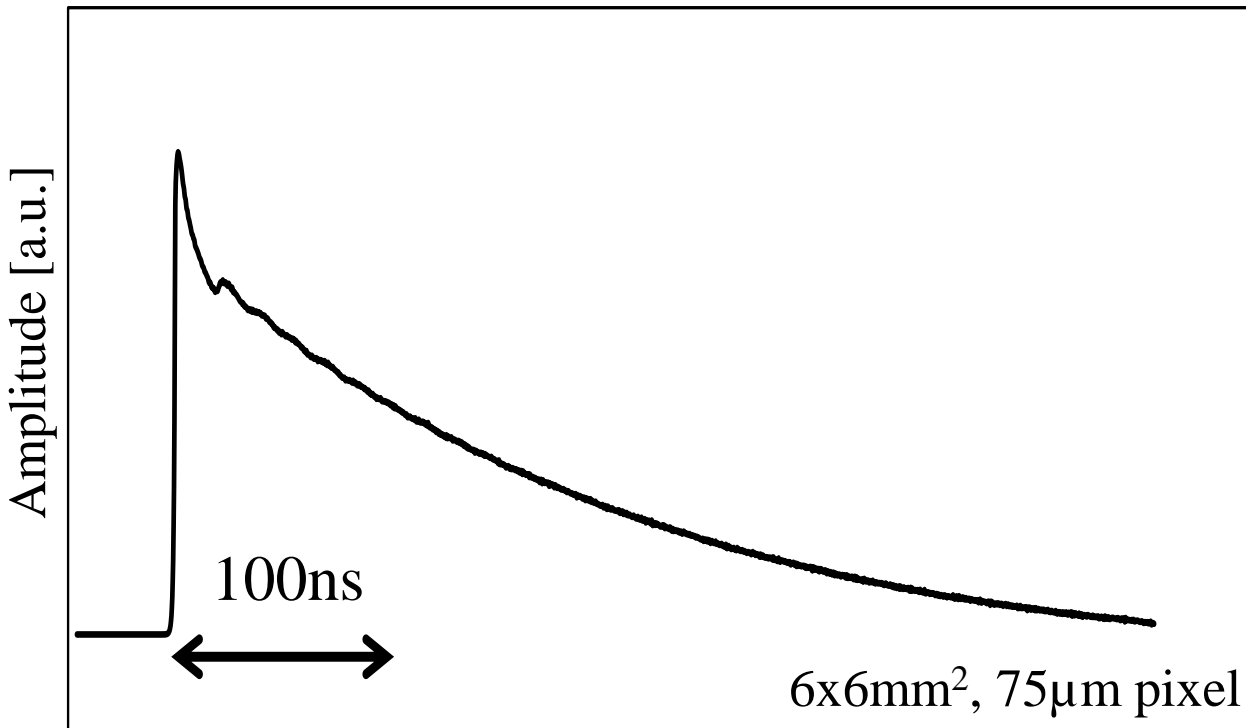
making the waveform sharper by adjusting quenching resistor and reducing terminal capacitance

Effect

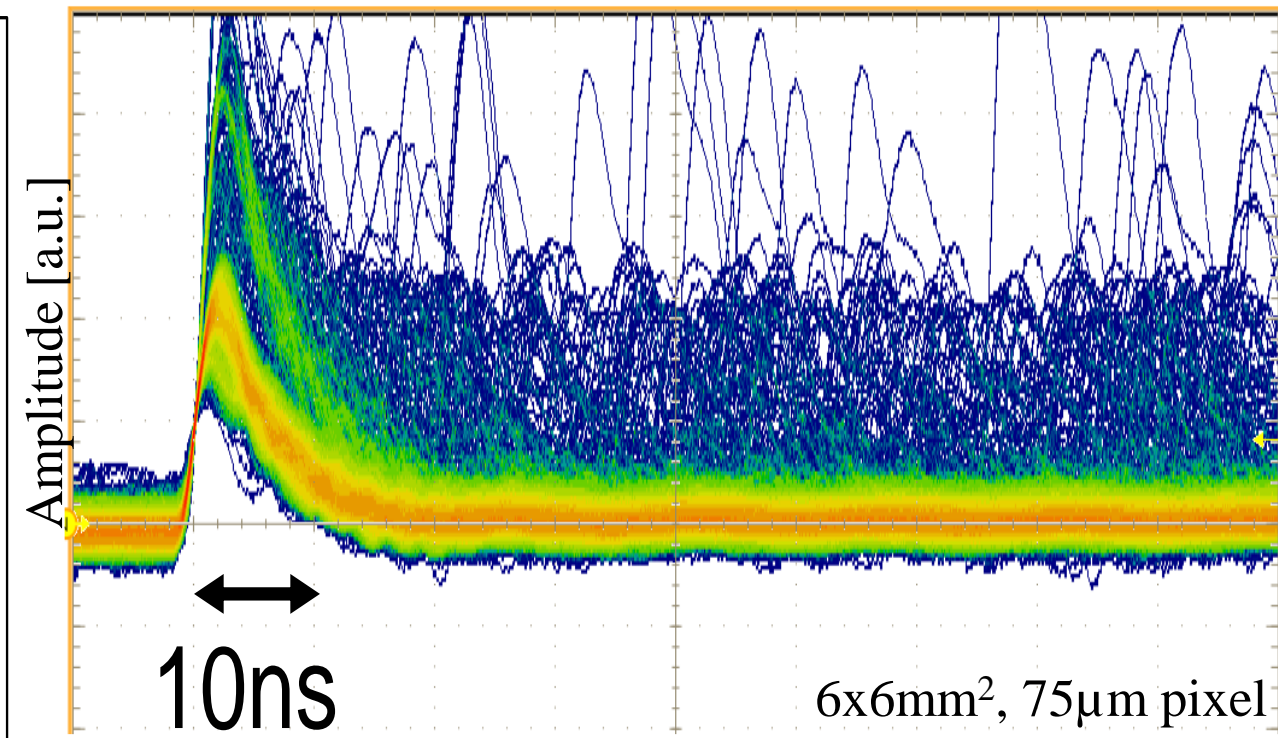
a lower trigger threshold can be used to take weaker Cherenkov light events (=event derived from lower energy particles can be observed)

Waveforms with pile-up**Waveforms without pile-up**

Conventional MPPC

FWHM: about 90ns

(average waveform)

MPPC with R_q and C_t optimization**FWHM: about 7ns**

(measurement result)



Large active area and small dead space with NUV transmissive window

Purpose

Realizing large photosensitive area coverage with small dead space

Approach

Applying Through Silicon Via (TSV) technology to eliminate the dead space

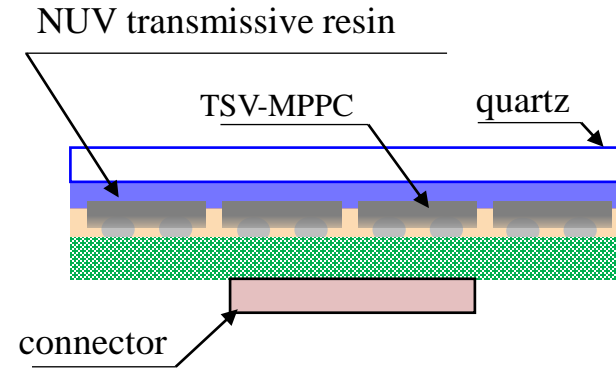
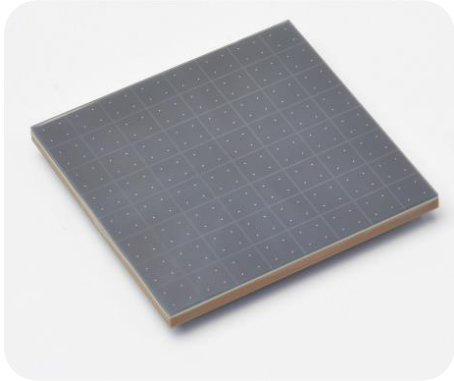
To protect device surface without compromising NUV sensitivity, attach quartz window on MPPC using NUV transmissive resin

Effect

Minimize light detection loss caused by dead space

Large active area and small dead space with NUV transmissive window

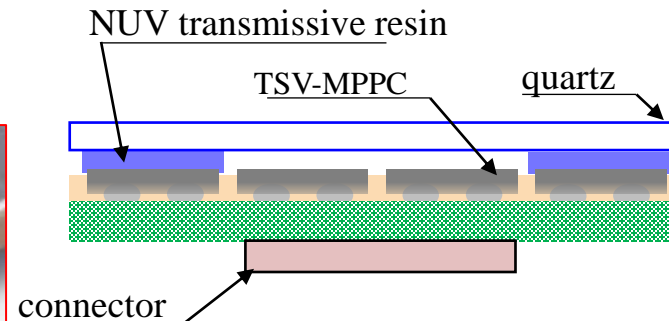
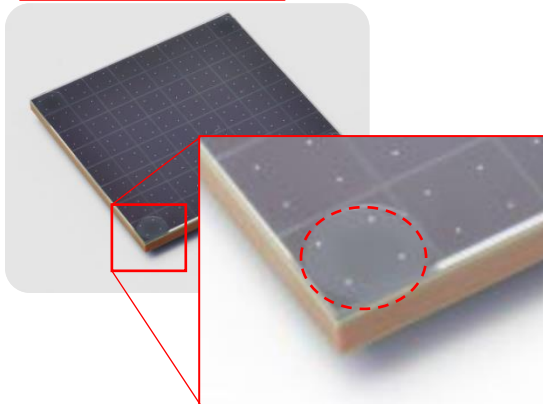
TYPE 1



✓ **Quartz is attached by resin over the entire surface**

➤ **Robust structure**

TYPE 2



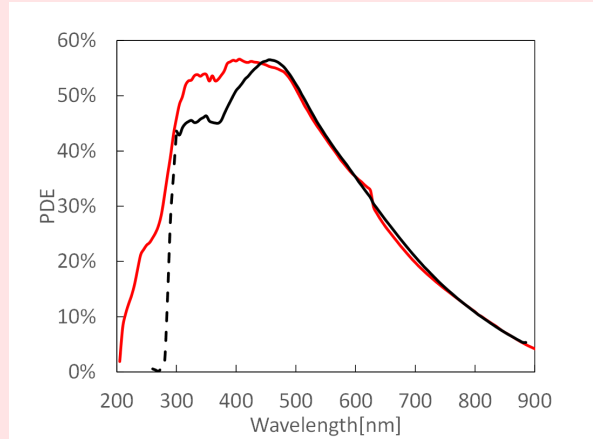
✓ **Quartz is attached by resin only on four corners of the surface**

➤ **Low crosstalk & high PDE**

Summary of MPPCs for NUV detection

1

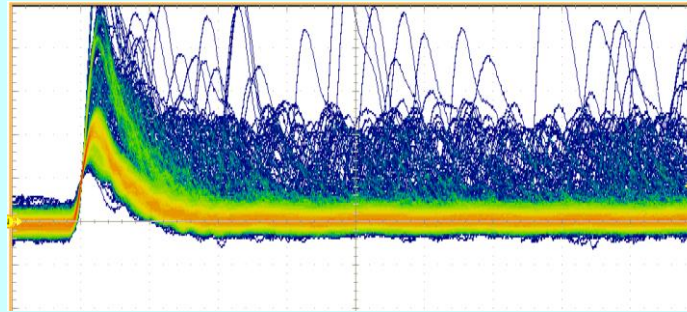
High NUV sensitivity



+

2

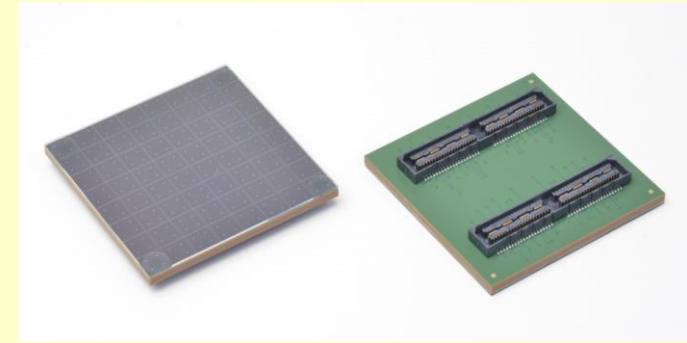
Pile-up suppression



+

3

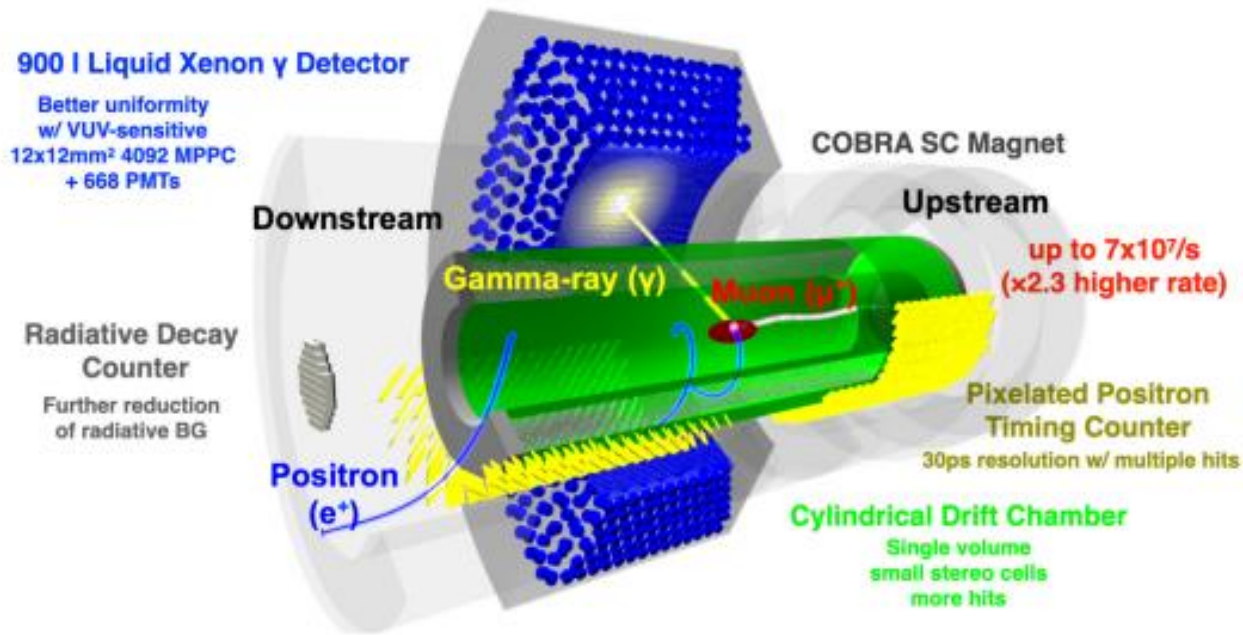
Large area with small dead space



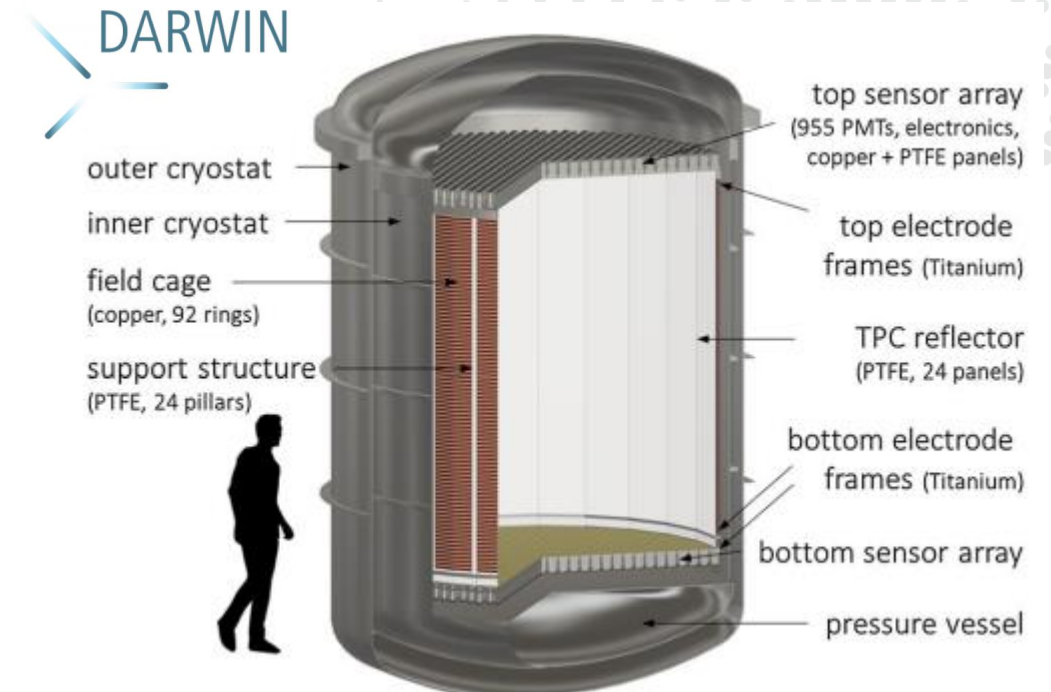
Hamamatsu produces **high NUV sensitive**, **low pile-up**, and **large area array** MPPC for Cherenkov light detection applications.

VUV sensitivity MPPC

for experiments utilizing liquid Xe as scintillation material



“The liquid xenon detector for the MEG II experiment to detect 52.8 MeV gamma-ray with large area VUV-sensitive MPPCs”,
NIM A 1046 (2023) 167720
<https://doi.org/10.1016/j.nima.2022.167720>



“Sensitivity of the DARWIN observatory to the neutrinoless double beta decay of ^{136}Xe ”,
Eur. Phys. J. C (2020) 80:808
<https://doi.org/10.1140/epjc/s10052-020-8196-z>

VUV sensitivity MPPC: development themes

1 Tolerance for humidity (suppress degradation of sensitivity)

The humidity tolerance should be high for long term reliability

2 Product packaging with low RI contamination

reduce false events by undesired RIs in product material

3 Low Dark Count Rate (DCR) at liquid Xe temperature

lower DCR leads to lower event threshold → more event collection



Improvement of humidity tolerance for LXe experiments

Purpose

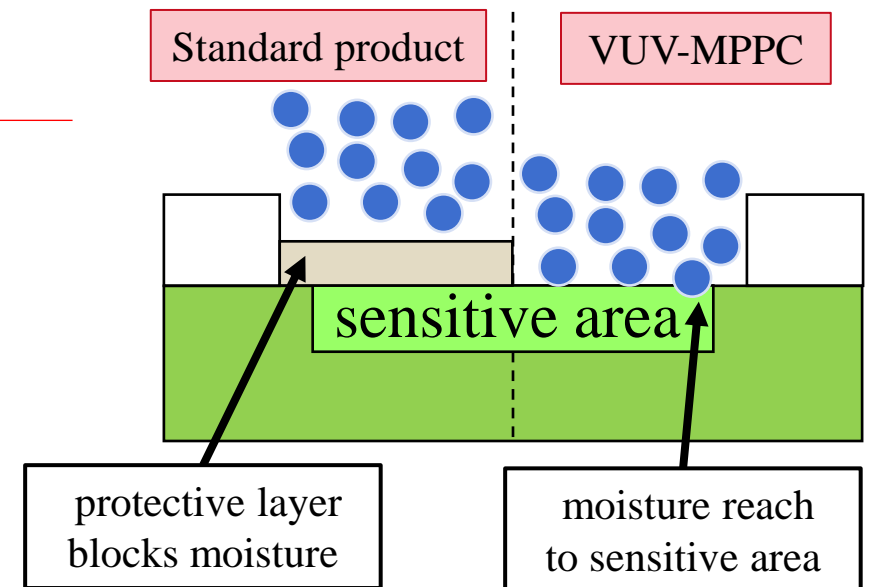
- VUV-MPPC has no protection layer for moisture protection
 - after long-term storage, sensitivity degradation is observed
- Construction of detectors for physical experiments takes 1+ years
 - humidity tolerance of MPPC itself is important

Approach

Reduction of defects on Si surface by improving the Si processing

Effect

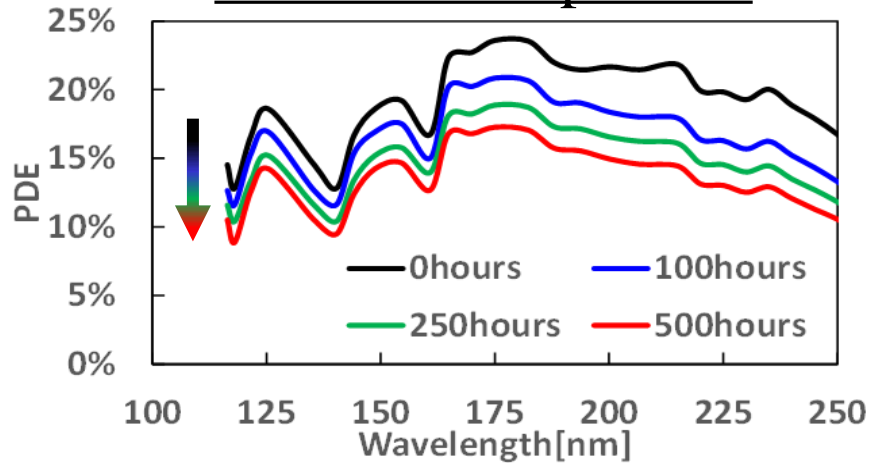
Sensitivity degradation is suppressed.





Improvement of humidity tolerance for LXe experiments

conventional process

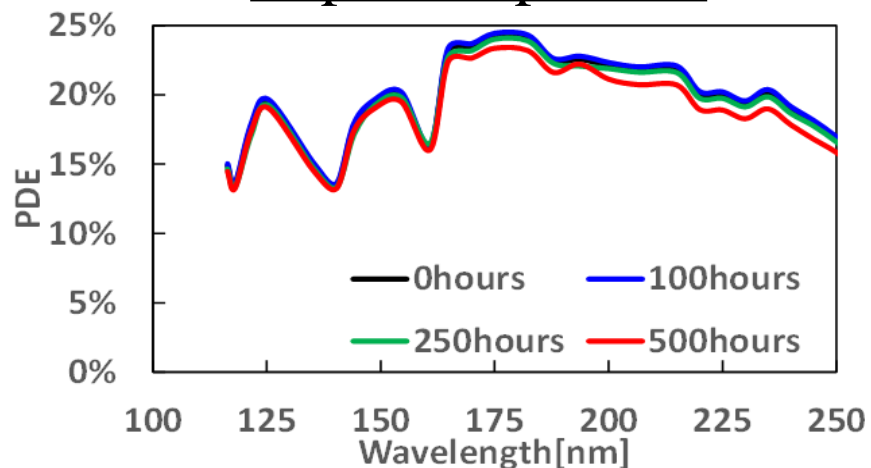


High Temperature/High humidity test

- Temperature : 60degC
- Humidity : 90%
- Improved process keeps sensitivity to 1000hours



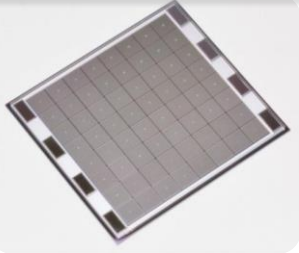
Improved process



Tolerance to 1000hurs @ 60degC, 90%
corresponds to 10years @ 25degC, 60%
(Vapor pressure accelerating model, confidence level :60%)

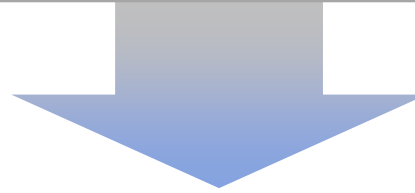
Achieve required tolerance for whole construction/operation period in physics experiments!

Past Prototype : Si substrate package



Pros : Low RI characteristics

Cons : Too high cost and handling difficulty

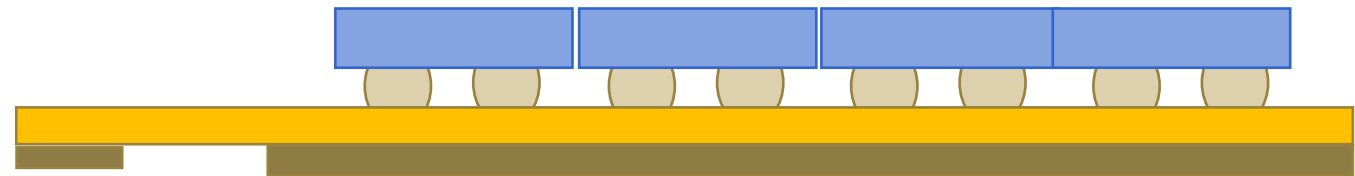
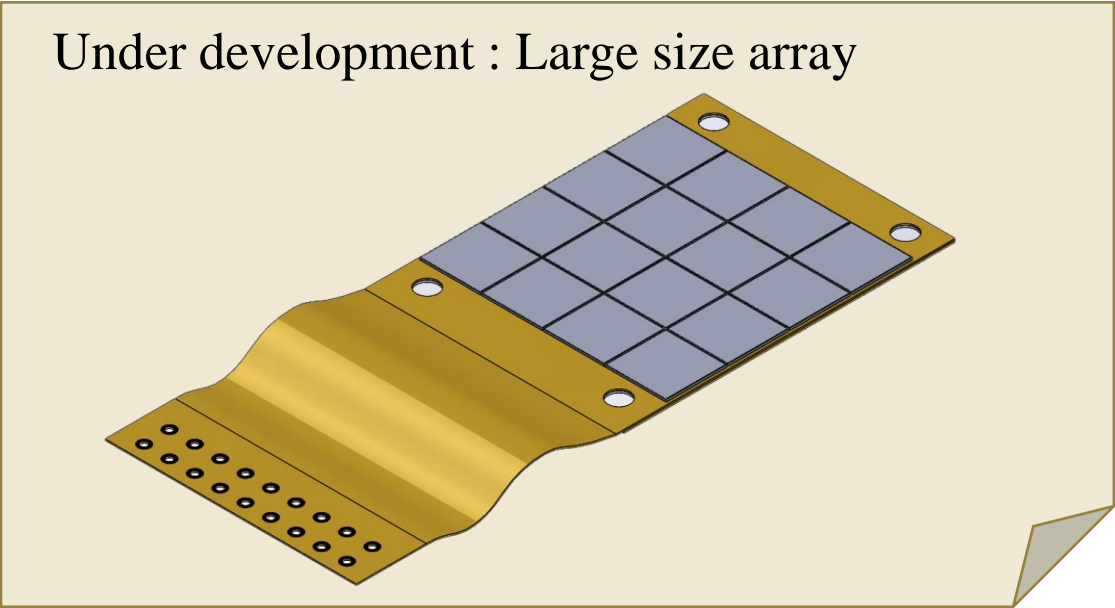
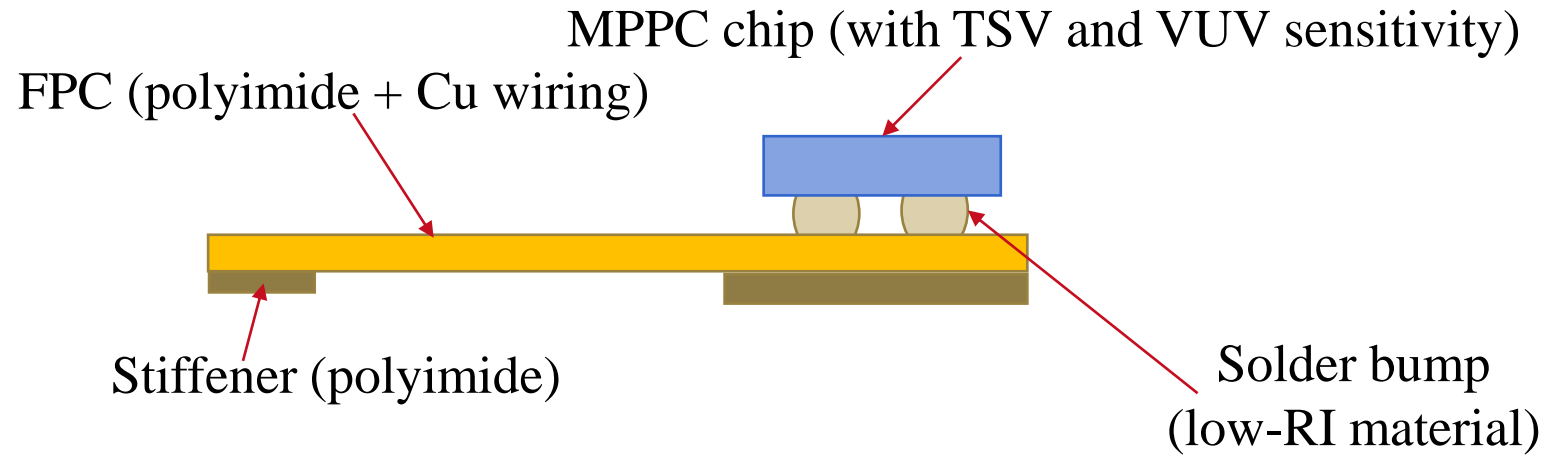
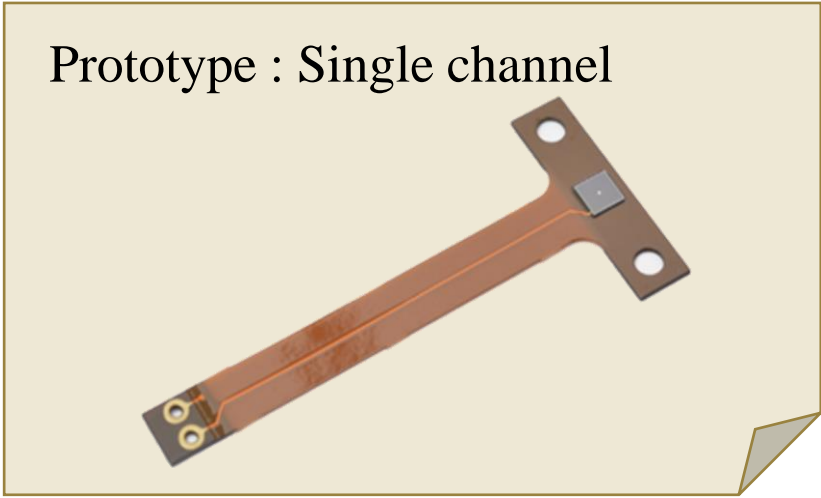


Current product : Chip on Film (CoF) package



Pros : Low cost and design flexibility

Cons : Not so great RI purity compared to Si substrate





Low Dark Count Rate for LXe experiments

Development target of Dark Count Rate (DCR):

below 0.01 cps/mm² at liquid Xe temperature (160-165K)
(comparable to Photomultiplier Tube's DCR)

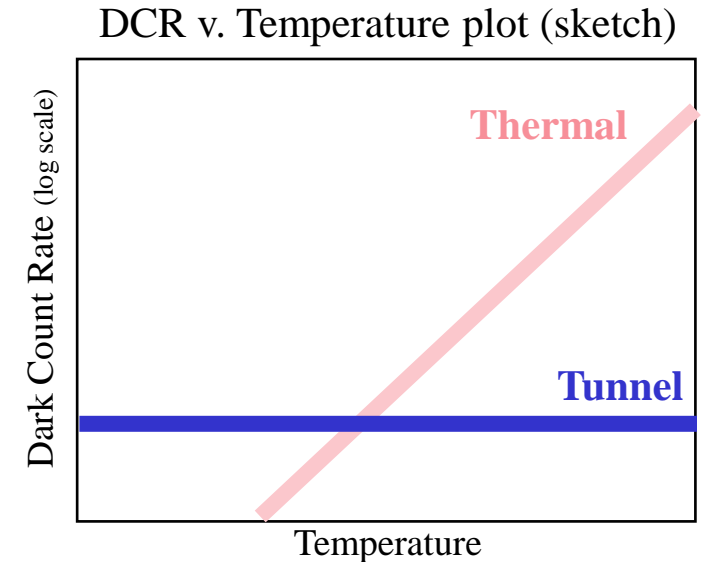
Two Components of DCR:

✓ **Thermally excited electrons**

- Higher rate for higher temperature
- Dominant at ambient temperature

✓ **Electrons traversing depletion layer by quantum tunnelling**

- ✓ Invariant to temperature changes
- ✓ **Dominant at liquid Xe temperature**





Low Dark Count Rate for LXe experiments

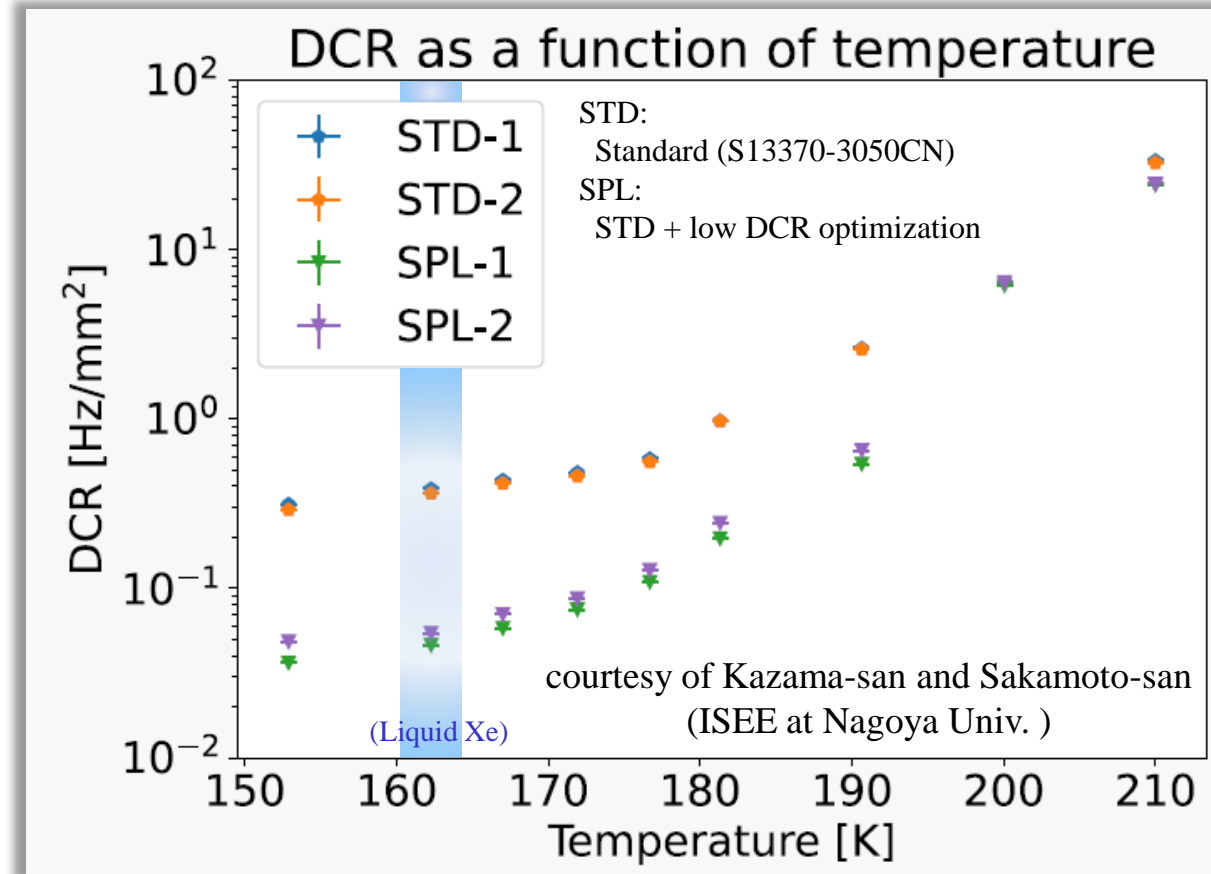
Difference from Standard VUV-MPPC:
optimization of wafer processing

- Aim to reduce E field in depletion layer

DCR is reduced to 1/10
from Standard VUV-MPPC
at liquid Xe temperature.

About 0.05cps/mm² is achieved.

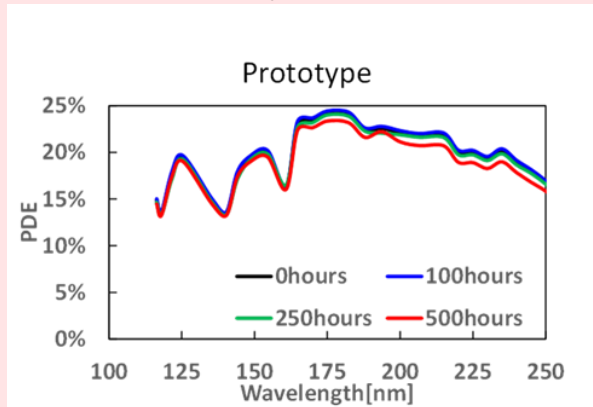
Standard / low DCR prototype VUV-MPPC comparison



Summary of MPPCs for VUV detection

1

Improvement of humidity tolerance



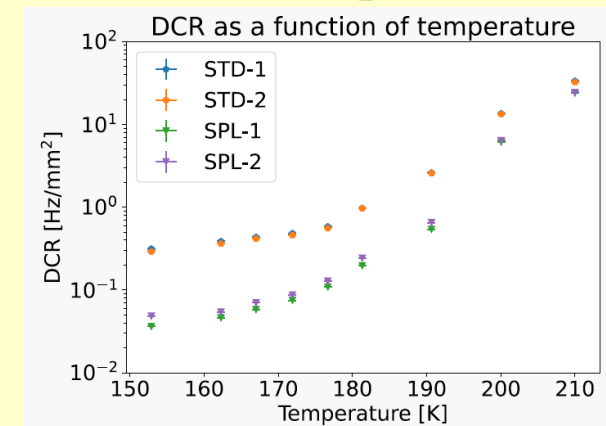
2

low RI PKG



3

low DCR at low Temperature



Hamamatsu produces **humidity tolerant**, **low RI**, and **low DCR at low Temp.** MPPC for experiments utilizing liquid Xe as scintillation material.

www.hamamatsu.com